INCH-POUND MIL-M-38510/301F <u>4 March 2004</u> SUPERSEDING MIL-M-38510/301E 14 February 2003

### MILITARY SPECIFICATION

# MICROCIRCUITS, DIGITAL, BIPOLAR LOW-POWER SCHOTTKY TTL, FLIP-FLOPS, CASCADABLE, MONOLITHIC SILICON

#### Inactive for new design after 18 April 1997.

This specification is approved for use by all Departments and Agencies of the Department of Defense.

The requirements for acquiring the product herein shall consist of this specification sheet and MIL-PRF 38535

1. SCOPE

1.1 <u>Scope.</u> This specification covers the detail requirements for monolithic silicon, low-power Schottky TTL, flipflops, bistable logic gate microcircuits. Two product assurance classes and a choice of case outlines and lead finishes are provided for each type and are reflected in the complete part number. For this product, the requirements of MIL-M-38510 have been superseded by MIL-PRF-38535, (see 6.3).

1.2 Part number. The part number is in accordance with MIL-PRF-38535, and as specified herein.

1.2.1 <u>Device types.</u> The device types are as follows:

Device type	<u>Circuit</u>
01	Dual J-K flip-flop with clear
02	Dual D type flip-flop with clear and preset
03	Dual J-K flip-flop with clear and preset
04	Dual J-K flip-flop with preset
05	Dual J-K flip-flop with preset and common clear and common clock
06	Hex D type flip-flop with common clear and common clock
07	Quad D type flip-flop with common clear and common clock
08	Dual, J-K flip-flop with clear
09	Dual, J- $\overline{K}$ flip-flop with clear and preset
10	Dual, J-K flip-flop with clear and preset

1.2.2 Device class. The device class is the product assurance level as defined in MIL-PRF-38535.

1.2.3 <u>Case outlines</u>. The case outlines are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
А	GDFP5-F14 or CDFP6-F14	14	Flat pack
В	GDFP4-14	14	Flat pack
С	GDIP1-T14 or CDIP2-T14	14	Dual-in-line
D	GDFP1-F14 or CDFP2-F14	14	Flat pack
E	GDIP1-T16 or CDIP2-T16	16	Dual-in-line
F	GDFP2-F16 or CDFP3-F16	16	Flat pack
Х	CQCC2-N20	20	Square leadless chip carrier
2	CQCC1-N20	20	Square leadless chip carrier

Comments, suggestions, or questions on this document should be addressed to: Commander, Defense Supply Center Columbus, ATTN: DSCC-VAS, 3990 East Broad St., Columbus, OH 43216-5000, or emailed to bipolar@dscc.dla.mil. Since contact information can change, you may want to verify the currency of this address information using the ASSIST Online database at www.dodssp.daps.mil.

AMSC N/A

1.3 Absolute maximum ratings.

Supply voltage range Input voltage range	
Storage temperature range	
Maximum power dissipation per flip-flop, (P <sub>D</sub> ) <u>1</u> /	. 25 mW
Lead temperature (soldering, 10 seconds)	. 300°C
Thermal resistance, junction to case ( $\theta_{JC}$ ):	
Cases A, B, C, D, E, F, X, and 2	(See MIL-STD-1835)
Junction temperature (T <sub>J</sub> ) <u>2</u> /	175°C

## 1.4 Recommended operating conditions.

Supply voltage ( $V_{CC}$ ) Minimum high level input voltage ( $V_{IH}$ ) Maximum low level input voltage ( $V_{IL}$ ) Case operating temperature range ( $T_C$ ) Input set up time:	2.0 V dc 0.7 V dc
Device types: 01, 03, 04, 05, 08, 09, and 10 02, 06, and 07 Input hold time:	
Device types: 01, 03, 04, 05, 08, and 10 02, 06, 07, and 09	

# 2. APPLICABLE DOCUMENTS

2.1 <u>General.</u> The documents listed in this section are specified in sections 3, 4, or 5 of this specification. This section does not include documents cited in other sections of this specification or recommended for additional information or as examples. While every effort has been made to ensure the completeness of this list, document users are cautioned that they must meet all specified requirements of documents cited in sections 3, 4, or 5 of this specification, whether or not they are listed.

#### 2.2 Government documents.

2.2.1 <u>Specifications and Standards</u>. The following specifications and standards form a part of this specification to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

#### DEPARTMENT OF DEFENSE SPECIFICATIONS

MIL-PRF-38535 - Integrated Circuits (Microcircuits) Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883	-	Test Method Standard for Microelectronics.
MIL-STD-1835	-	Interface Standard Electronic Component Case Outlines

(Opping of these decuments are evaluable enline at http://popint.demo.dla.mil.evi.il.co.crah / enumy de door

(Copies of these documents are available online at http://assist.daps.dla.mil;quicksearch/ or www.dodssp.daps.mil or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

 $<sup>\</sup>underline{1}$  Must withstand the added P<sub>D</sub> due to short-circuit test (e.g., I<sub>OS</sub>).

<sup>2/</sup> Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with MIL-PRF-38535.

2.2 <u>Order of precedence.</u> In the event of a conflict between the text of this specification and the references cited herein, the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

#### 3. REQUIREMENTS

3.1 <u>Qualification</u>. Microcircuits furnished under this specification shall be products that are manufactured by a manufacturer authorized by the qualifying activity for listing on the applicable qualified manufacturers list before contract award (see 4.3 and 6.4).

3.2 <u>Item requirements.</u> The individual item requirements shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

3.3 <u>Design, construction, and physical dimensions.</u> The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein.

3.3.1 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.

3.3.2 Logic diagrams. The logic diagrams shall be as specified on figure 2.

3.3.3 <u>Truth tables</u>. The truth tables and logic equations shall be as specified on figure 3.

3.3.4 <u>Schematic circuits</u>. The schematic circuits shall be maintained by the manufacturer and made available to the qualifying activity and the preparing activity upon request.

3.3.5 Case outlines. The case outlines shall be as specified in 1.2.3.

3.4 Lead material and finish. The lead material and finish shall be in accordance with MIL-PRF-38535 (see 6.6).

3.5 <u>Electrical performance characteristics</u>. The electrical performance characteristics are as specified in table I, and apply over the full recommended case operating temperature range, unless otherwise specified.

3.6 <u>Electrical test requirements.</u> The electrical test requirements for each device class shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table III.

3.7 Marking. Marking shall be in accordance with MIL-PRF-38535.

3.8 <u>Microcircuit group assignment</u>. The devices covered by this specification shall be in microcircuit group number 10 (see MIL-PRF-38535, appendix A).

# 4. VERIFICATION

4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit, or function as described herein.

4.2 <u>Screening</u>. Screening shall be in accordance with, MIL-PRF-38535 and shall be conducted on all devices prior to qualification and quality conformance inspection. The following additional criteria shall apply:

- a. The burn-in test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II, except interim electrical parameters test prior to burn-in is optional at the discretion of the manufacturer.
- c. Additional screening for space level product shall be as specified in MIL-PRF-38535, appendix B.
- 4.3 <u>Qualification inspection</u>. Qualification inspection shall be in accordance with MIL-PRF-38535.

4.4 <u>Technology Conformance inspection (TCI)</u>. Technology conformance inspection shall be in accordance with MIL-PRF-38535 and herein for groups A, B, C, and D inspections (see 4.4.1 through 4.4.4).

- 4.4.1 Group A inspection. Group A inspection shall be in accordance with table III of MIL-PRF-38535 and as follows:
  - a. Tests shall be as specified in table II herein.
  - b. Subgroups 4, 5, and 6 shall be omitted.
- 4.4.2 Group B inspection. Group B inspection shall be in accordance with table II MIL-PRF-38535.
- 4.4.3 Group C inspection. Group C inspection shall be in accordance with table IV of MIL-PRF-38535 and as follows:
  - a. End-point electrical parameters shall be as specified in table II herein.
  - b. The steady-state life test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.

4.4.4 <u>Group D inspection</u>. Group D inspection shall be in accordance with table V of MIL-PRF-38535. End-point electrical parameters shall be as specified in table II herein.

4.5 <u>Methods of inspection</u>. Methods of inspection shall be specified and as follows:

4.5.1 <u>Voltage and current.</u> All voltages given are referenced to the microcircuit ground terminal. Currents given are conventional and positive when flowing into the referenced terminal.

Test	Symbol	Conditions <u>1</u> /	Device	Li	Limits		
	,	$-55^{\circ}C \le T_{C} \le +125^{\circ}C$ unless otherwise specif		types	Min	Max	Unit
High level output voltage	V <sub>OH</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = -400 μA		All	2.5		V
Low level output voltage	V <sub>OL</sub>	$V_{CC} = 4.5 \text{ V}, I_{OL} = 4 \text{ mA}$		All		0.4	V
Input clamp voltage	V <sub>IC</sub>	$V_{CC} = 4.5 \text{ V}, \text{ I}_{IN} = -18 \text{ mA},$ $T_C = +25^{\circ}\text{C}$		All		-1.5	V
Low level input current	I <sub>IL1</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 0.4 \text{ V}$	<u>2</u> /	01, 03, 04	030 010	360 360	mA
ourion			2/	05, 08, 10 06, 07	075	400	
	I <sub>IL2</sub>		<u>2</u> / <u>3</u> / <u>3</u> /	02, 09	030	400	
		4	<u>3</u> /	06 07	075 075	420 420	
	I <sub>IL3</sub>		<u>4</u> / <u>4</u> /	01, 08 03, 04, 10	060 060	720 760	
	I <sub>IL4</sub>		<u>5</u> /	01, 02, 03, 04, 05, 08, 09, 10	060	800	
	I <sub>IL5</sub>		<u>6</u> /	02	060	-1.20	
	I <sub>IL6</sub>	_	<u>4</u> /	05	12	-1.52	
	I <sub>IL7</sub>		<u>6</u> / <u>6</u> /	05 09	120 060	-1.60 -1.60	
High level input current	I <sub>IH1</sub>	$V_{CC} = 5.5 \text{ V},  V_{\text{IN}} = 2.7 \text{ V}$	<u>7</u> /	All		20	μΑ
	I <sub>IH2</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	<u>7</u> /	All		100	
	I <sub>IH3</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 2.7 \text{ V}$	<u>8</u> /	02, 09		40	
	I <sub>IH4</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	<u>8</u> /	02, 09		200	
	I <sub>IH5</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 2.7 \text{ V}$	<u>9</u> /	01, 02, 03, 04, 05, 08, 10		60	
	I <sub>IH6</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	<u>9</u> /	01, 02, 03, 04, 05, 08, 10		300	
	I <sub>IH7</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 2.7 \text{ V}$	<u>10</u> /	01, 03, 04, 08, 09, 10		80	
	I <sub>IH8</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	<u>10</u> /	01, 03, 04, 08, 09, 10		400	
	I <sub>IH9</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 2.7 \text{ V}$	<u>6</u> /	05		120	
	I <sub>IH10</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	<u>6</u> /	05		600	
	I <sub>IH11</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 2.7 \text{ V}$	<u>4</u> /	05		160	
	I <sub>IH12</sub>	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	<u>4</u> /	05		800	

# TABLE I. Electrical performance characteristics.

See footnotes at end of table.

Test	Symbol	Conditions <u>1</u> /	Device	L	imits	Unit
		$-55^{\circ}C \le T_C \le +125^{\circ}C$	types	Min	Max	
		unless otherwise specified				
Short circuit output	los	$V_{CC} = 5.5 V \frac{11}{2}$	01, 02, 03,	-15	-100	mA
current		$V_{IN} = 0 V$	05, 06, 07,			
			08, 09			
			04, 10	-15	-130	
Supply current	Icc	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	01, 02, 03,		8	mA
			04, 05, 08			
			09, 10			
			06		26	
			07		18	
Maximum clock	f <sub>MAX</sub>	$V_{CC} = 5.0 V$	01, 03, 04	25		MHz
frequency		$C_{L} = 50 \text{ pF} \pm 10\%$	05, 06, 07			
		$R_L = 2k\Omega \pm 5\%$	08, 10			
			02, 09	20		
Propagation delay to	t <sub>PLH1</sub>	1	01, 03, 04,	5	32	ns
high logic level			05, 08, 10			
(clear or preset			02, 09	5	39	
to output)			07	5	51	
Propagation delay to	t <sub>PHL1</sub>		01, 03, 04,	5	40	ns
low logic level			05, 08, 10			
(clear or preset			02, 09	5	59	
to output)			06	5	52	
			07	5	55	
Propagation delay to	t <sub>PLH2</sub>	1	01, 03, 04,	5	32	ns
high logic level			05, 08, 10			
(clock to output)			02, 09	5	39	
			06	5	47	
			07	5	46	
Propagation delay to	t <sub>PHL2</sub>	1	01, 03, 04,	5	42	ns
low logic level			05, 08, 10			
(clock to output)			02, 09	5	59	1
· · · /			06	5	52	1
			07	5	55	

# TABLE I. Electrical performance characteristics - Continued.

1/ See table III for complete terminal conditions.

- $\frac{1}{2}$ / Input condition J or K (device types 01, 03, 04, 05, 08, and 10); and D (device types 06 and 07).
- <u>3</u>/ Input condition D (device type 02); clock or clear (device types 06 and 07); and J or  $\overline{K}$  (device type 09).
- 4/ Input condition Clock.
- 5/ Input condition Clear or preset (device types 03 and 10); clear (device types 01 and 08); preset or clock (device types 02 and 09); and preset (device types 04 and 05).
- 6/ Input condition Clear.
- <u>7</u>/ Input condition J or K (device types 01, 03, 04, 05, 08, and 10); D (device type 02); J or K (device type 09); and D, clear, clock (device types 06 and 07).
- 8/ Input condition Preset or clock.
- <u>9</u>/ Input condition Clear or preset (device types 03 and 10); clear (device types 01, 02, and 08); and preset (device types 04 and 05).
- 10/ Input condition Clock (device type 01, 03, 04, 08, and 10); and clear (device type 09).
- 11/ Not more than one output should be shorted at a time.

	Subgroups (see table III)				
MIL-PRF-38535	Class S	Class B			
test requirements	devices	devices			
Interim electrical parameters	1	1			
Final electrical test parameters	1*, 2, 3, 7, 9, 10, 11	1*, 2, 3, 9			
Group A test requirements	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3, 7, 8, 9, 10, 11			
Group C end-point electrical parameters	1, 2, 3, 9, 10, 11	1, 2, 3			
Group D end-point electrical parameters	1, 2, 3	1, 2, 3			

# TABLE II. Electrical test requirements.

\*PDA applies to subgroup 1.

# 5. PACKAGING

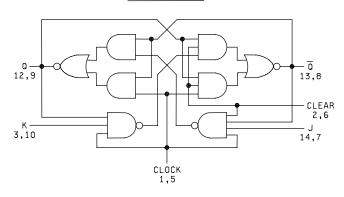
5.1 <u>Packaging requirements.</u> For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When actual packaging of materiel is to be performed by DoD personnel, these personnel need to contact the responsible packaging activity to ascertain requisite packaging requirements. Packaging requirements are maintained by the Inventory Control Point's packaging activity within the Military Department of Defense Agency, or within the Military Department's System Command. Packaging data retrieval is available from the managing Military Department's or Defense Agency's automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.

	Pin symbols device type 01		,			Pin symbols device type 03		Pin symbols device type 04		Pin symbols device type 05	
Pin number	Cases 2, X	Cases A, B, C, and D	Cases 2, X	Cases A, B, C, and D	Cases 2, X	Cases E, F	Cases 2, X	Cases A, B, C, and D	Cases 2, X	Cases A, B, C, and D	
1	NC	CLK1	NC	CLR1	NC	CLK1	NC	CLK1	NC	CLR1	
2	CLK1	CLR1	CLR1	1D	CLK1	1K	CLK1	1K	CLR	1K	
3	CLR1	1K	1D	CLK1	1K	1J	1K	1J	1K	1J	
4	1K	V <sub>CC</sub>	CLK1	PS1	1J	PS1	1J	PS1	1J	PS1	
5	NC	CLK2	NC	1Q	PS1	1Q	NC	1Q	NC	1Q	
6	Vcc	CLR2	PS1	1 Q	NC	1 Q	PS1	1 Q	PS1	1 Q	
7	NC	2J	NC	GND	1Q	2 Q	NC	GND	NC	GND	
8	CLK2	2 Q	1Q	2 Q	1 Q	GND	1Q	2 Q	1Q	2 Q	
9	CLR2	2Q	1 Q	2Q	2Q	2Q	1 Q	2Q	1 Q	2Q	
10	2J	2K	GND	PS2	GND	PS2	GND	PS2	GND	PS2	
11	NC	GND	NC	CLK2	NC	2J	NC	2J	NC	2J	
12	2 Q	1Q	2 Q	2D	2Q	2K	2Q	2K	2 Q	2K	
13	2Q	1 Q	2Q	CLR2	PS2	CLK2	2Q	CLK2	2Q	CLK	
14	2K	1J	PS2	V <sub>CC</sub>	2J	CLR2	PS2	V <sub>CC</sub>	PS2	V <sub>CC</sub>	
15	NC		NC		2K	CLR1	NC		NC		
16	GND		CLK2		NC	V <sub>CC</sub>	2J		2J		
17	NC		NC		CLK2		NC		NC		
18	1Q		2D		CLR2		2K		2K		
19	1 Q		CLR2		CLR1		CLK2		CLK		
20	1J		V <sub>CC</sub>		V <sub>CC</sub>		V <sub>CC</sub>		V <sub>CC</sub>		

FIGURE 1. Terminal connections.

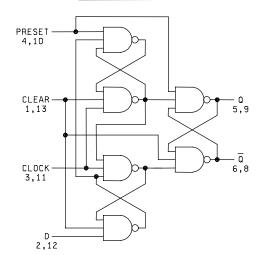
	Pin symbols device type 06					Pin symbols device type 08		Pin symbols device type 09		Pin symbols device type 10	
Pin number	Cases 2, X	Cases E, F	Cases 2, X	Cases E, F	Cases 2, X	Cases A, B, C, and D	Cases 2, X	Cases E, F	Cases 2, X	Cases E, F	
1	NC	CLR	NC	CLR	NC	1J	NC	1CLR	NC	1CLK	
2	CLR	1Q	CLR	1Q	1J	1 Q	1CLR	1J	1CLK	1PS	
3	1Q	1D	1Q	1 Q	1 Q	1Q	1J	1 K	1PS	1CLR	
4	1D	2D	1 Q	1D	1Q	1K	1 K	1CLK	1CLR	1J	
5	2D	2Q	1D	2D	NC	2Q	1CLK	1PS	1J	V <sub>CC</sub>	
6	NC	3D	NC	2 Q	1K	2 Q	NC	1Q	NC	2CLK	
7	2Q	3Q	2D	2Q	NC	GND	1PS	1 Q	V <sub>CC</sub>	2PS	
8	3D	GND	2 Q	GND	2Q	2J	1Q	GND	2CLK	2CLR	
9	3Q	CLK	2Q	CLK	2 Q	2CLK	1 Q	2 Q	2PS	2J	
10	GND	4Q	GND	3Q	GND	2CLR	GND	2Q	2CLR	2 Q	
11	NC	4D	NC	3Q	NC	2K	NC	2PS	NC	2Q	
12	CLK	5Q	CLK	3D	2J	1CLK	2Q	2CLK	2J	2K	
13	4Q	5D	3Q	4D	2CLK	1CLR	2Q	2K	2 Q	GND	
14	4D	6D	зQ	4 Q	2CLR	V <sub>CC</sub>	2PS	2J	2Q	1 Q	
15	5Q	6Q	3D	4Q	NC		2CLK	2CLR	2K	1Q	
16	NC	V <sub>CC</sub>	NC	V <sub>CC</sub>	2K		NC	V <sub>CC</sub>	NC	1K	
17	5D		4D		NC		2K		GND		
18	6D		4 Q		1CLK		2J		1 Q		
19	6Q		4Q		1CLR		2CLR		1Q		
20	V <sub>CC</sub>		V <sub>CC</sub>		V <sub>CC</sub>		V <sub>CC</sub>		1K		

FIGURE 1. <u>Terminal connections</u> - Continued.



# (Pin numbers shown apply to the DIP and flat packs only) $\underbrace{\text{DEVICE TYPE 01}}_{\text{DEVICE TYPE 01}}$





DEVICE TYPE 03

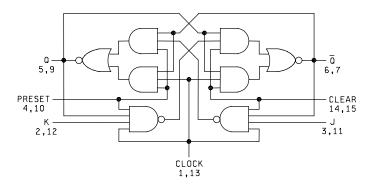
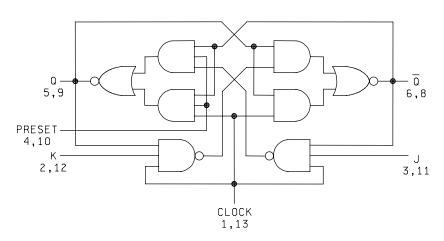


FIGURE 2. Logic Diagrams.

(Pin numbers shown apply to the DIP and flat packs only)



DEVICE TYPE 05

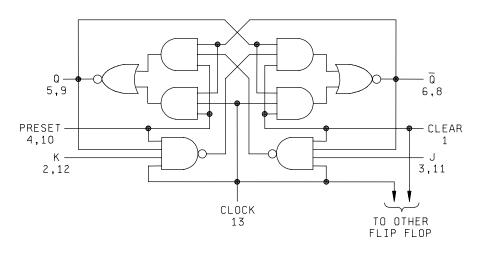


FIGURE 2. Logic Diagrams - Continued.

(Pin numbers shown apply to the DIP and flat packs only)

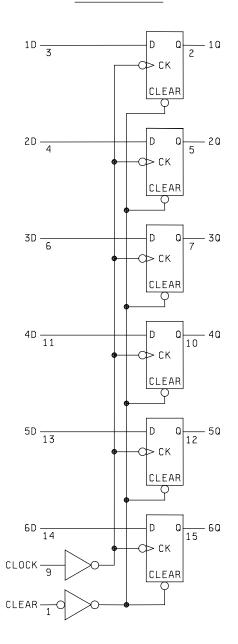
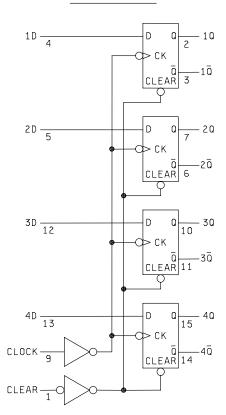


FIGURE 2. Logic Diagrams - Continued.

(Pin numbers shown apply to the DIP and flat packs only)



DEVICE TYPE 08

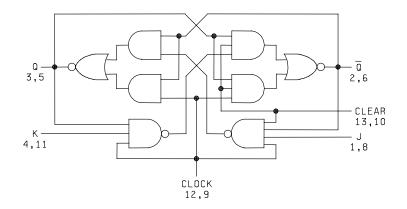
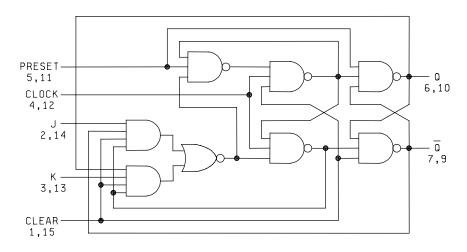


FIGURE 2. Logic Diagrams - Continued.

(Pin numbers shown apply to the DIP and flat packs only)



DEVICE TYPE 10

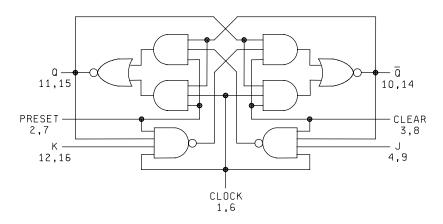


FIGURE 2. Logic Diagrams - Continued.

# **DEVICE TYPE 01**

	OUT	PUTS			
CLEAR	CLOCK	CLOCK J K			IQ
L	Х	Х	Х	L	Н
Н	$\downarrow$	L	L	$Q_0$	$\overline{Q}_{0}$
Н	$\downarrow$	Н	L	Н	L
Н	$\downarrow$	L	Н	L	Н
Н	$\downarrow$	Н	Н	TOGGLE	
Н	Н	Х	Х	$Q_0$	Q 0

H = high level (steady state)

L = low level (steady state)

X = irrelevant

 $\downarrow$  = transition from high to low level

 $Q_0$  = the level of Q before the indicated input conditions were established.

TOGGLE: Each output changes to the complement of its previous level on each  $\downarrow$  clock transition.

# DEVICE TYPE 02

	OUTF	PUTS			
PRESET	CLEAR	CLEAR CLOCK D			IQ
L	Н	Х	Х	Н	L
Н	L	Х	Х	L	Н
L	L	Х	Х	H*	H*
Н	H	Ť	Н	Н	L
Н	H	Ť	L	L	Н
Н	Н	L	Х	$Q_0$	Q <sub>0</sub>

H = high level (steady state)

L = low level (steady state)

X = irrelevant

 $\uparrow$  = transition from low to high level

 $Q_0$  = the level of Q before the indicated steady state input conditions were established.

\* This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) level.

FIGURE 3. Truth tables.

		INPUTS			OUTF	UTS
PRESET	CLEAR	CLOCK	J	К	Q	IQ
L	Н	Х	Х	Х	Н	L
Н	L	Х	Х	Х	L	Н
L	L	Х	Х	Х	H*	H*
Н	Н	$\rightarrow$	L	L	<b>Q</b> <sub>0</sub>	Q <sub>0</sub>
Н	Н	$\downarrow$	Н	L	Н	L
Н	Н	$\rightarrow$	L	Н	L	Н
Н	Н	$\rightarrow$	Н	Н	TOG	GLE
Н	Н	Н	Х	Х	Q <sub>0</sub>	$\overline{Q}_0$

# DEVICE TYPES 03 AND 10

H = high level (steady state)

L = low level (steady state)

X = irrelevant

 $\downarrow$  = transition from high to low level

 $Q_0$  = the level of Q before the indicated steady state input conditions were established.

- TOGGLE: Each output changes to the complement of its previous level on each ↓ clock transition.
- \* This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) level.

## **DEVICE TYPE 04**

	INPUT	S		OUTF	PUTS
PRESET	CLOCK	J	К	Q	Q
L	Н	Х	Х	Н	L
Н	$\downarrow$	L	L	$Q_0$	Q <sub>0</sub>
Н	$\rightarrow$	Н	L	Н	L
Н	$\rightarrow$	L	Н	L	Н
Н	$\downarrow$	Н	Н	TOG	GLE
Н	Н	Х	Х	$Q_0$	$\overline{Q}_0$

H = high level (steady state)

L = low level (steady state)

X = irrelevant

 $\downarrow$  = transition from high to low level

- $\hat{Q}_0$  = the level of Q before the indicated input conditions were established.
- TOGGLE: Each output changes to the complement of its previous level on each  $\downarrow$  clock transition.

		INPUTS			OUTF	UTS
PRESET	CLEAR	CLOCK	J	К	Q	IQ
L	Н	Х	Х	Х	Н	L
Н	L	Х	Х	Х	L	Н
L	L	Х	Х	Х	H*	H*
Н	Н	$\rightarrow$	L	L	<b>Q</b> <sub>0</sub>	Q <sub>0</sub>
Н	Н	$\downarrow$	Н	L	Н	L
Н	Н	$\rightarrow$	L	Н	L	Н
Н	Н	$\rightarrow$	Н	Н	TOG	GLE
Н	Н	Н	Х	Х	Q <sub>0</sub>	Q <sub>0</sub>

# **DEVICE TYPES 05**

H = high level (steady state)

L = low level (steady state)

X = irrelevant

 $\downarrow$  = transition from high to low level

 $Q_0$  = the level of Q before the indicated steady state input conditions were established.

- TOGGLE: Each output changes to the complement of its previous level on each ↓ clock transition.
- \* This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) level.

#### **DEVICE TYPE 06**

	INPUTS		OUTPUT
CLEAR	CLOCK	D	Q
L	Х	Х	L
Н	<b>↑</b>	Н	Н
Н	Ť	L	L
Н	L	Х	$Q_0$

H = high level (steady state)

L = low level (steady state)

X = irrelevant

 $\uparrow$  = transition from low to high level

Q<sub>0</sub> = the level of Q before the indicated steady state input conditions were established.

# **DEVICE TYPE 07**

	INPUTS		OUT	PUT
CLEAR	CLOCK	D	Q	IQ
L	Х	Х	L	Н
Н	Ť	Н	H	L
Н	Ť	L	L	L
Н	L	Х	Q <sub>0</sub>	Q <sub>0</sub>

H = high level (steady state)

L = low level (steady state)

X = irrelevant

 $\uparrow$  = transition from low to high level

 $\dot{Q}_0$  = the level of Q before the indicated steady state input conditions were established.

## **DEVICE TYPE 08**

	INPUT	S		OUT	PUTS
CLEAR	CLOCK	J	K	Q	IQ
L	Х	Х	Х	L	Н
Н	1	L	L	$Q_0$	$\overline{Q}_{0}$
Н	<b>↑</b>	Н	L	Н	L
Н	↑	L	Н	L	Н
Н	↑	Н	Н	TOG	GLE

H = high level (steady state) L = low level (steady state)

X = irrelevant

 $\uparrow$  = transition from low to high level

 $Q_0$  = the level of Q before the indicated input conditions were established.

TOGGLE: Each output changes to the complement of its previous level on each clock transition.

		INPUTS			OUTF	UTS
PRESET	CLEAR	CLOCK	J	ĸ	Q	IQ
L	Н	Х	Х	Х	Н	L
Н	L	Х	Х	Х	L	H
L	L	Х	Х	Х	H*	H*
н	Н	↑	L	L	L	Н
Н	Н	↑	Н	L	TOG	GLE
Н	Н	1	L	Н	Q <sub>0</sub>	$\overline{Q}_0$
Н	Н	↑	Н	Н	Н	L
Н	Н	L	Х	Х	Q <sub>0</sub>	Q <sub>0</sub>

# DEVICE TYPE 09

H = high level (steady state)

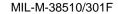
L = low level (steady state)

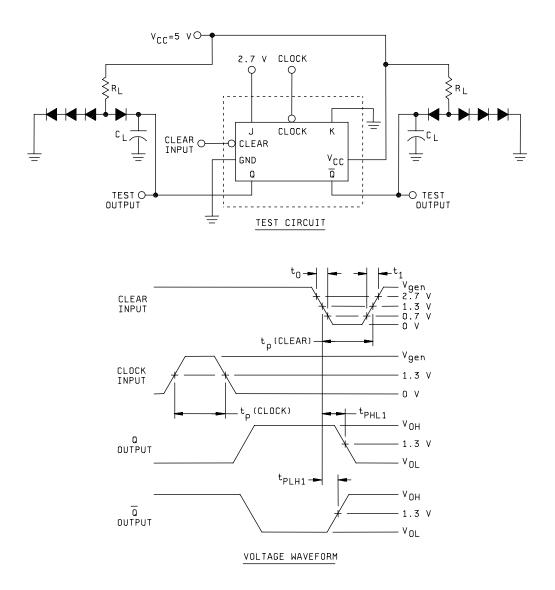
X = irrelevant

 $\uparrow$  = transition from low to high level

 $\dot{Q}_0$  = the level of Q before the indicated steady state input conditions were established.

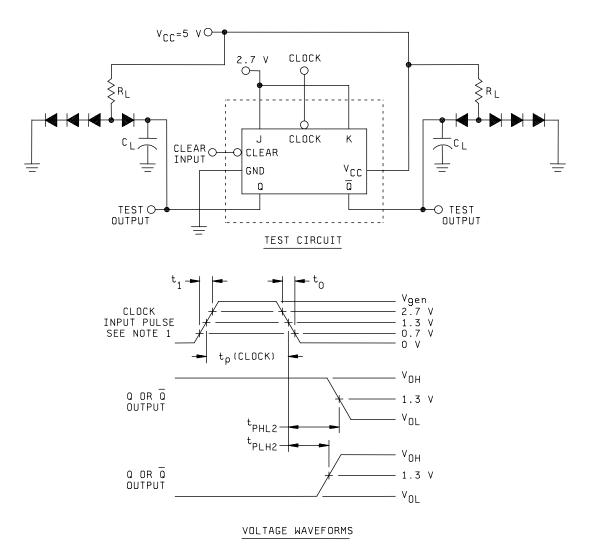
- TOGGLE: Each output changes to the complement of its previous level on each ↑ clock transition.
- \* This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) level.





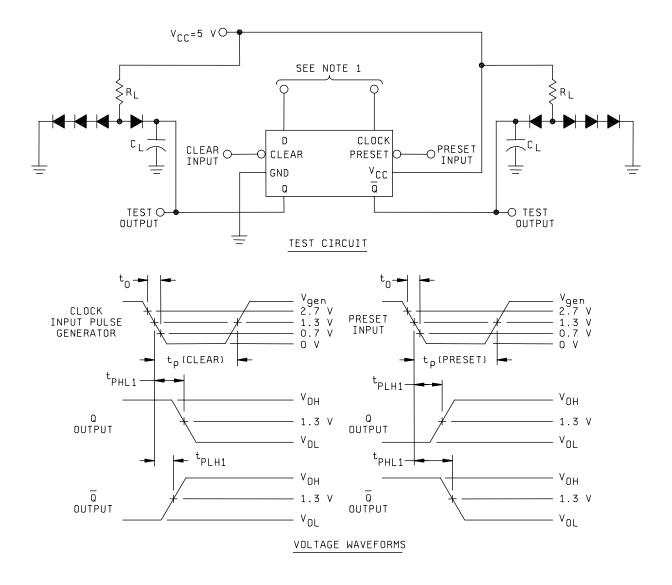
- 1. Clear inputs dominate regardless of the state of clock or J-K inputs.
- 2. Clear input pulse characteristics:  $V_{gen}$  = 3 V,  $t_1 \le 15$  ns,  $t_0 \le 6$  ns,  $t_p$  (clear) = 30 ns, PRR  $\le 1$  MHz.
- 3. All diodes are 1N3064, or equivalent.
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 k\Omega \pm 5\%$ .
- 6. Clock input pulse characteristics:  $V_{gen}$  = 3 V,  $t_p$ (clock) = 25 ns, PRR  $\leq$  1 MHz.

FIGURE 4. Clear switching time test circuit and waveforms for device types 01 and 08.



- 1. Clock input characteristics for  $t_{PLH}$ ,  $t_{PHL}$  (clock to output),  $V_{gen} = 3 \text{ V}$ ,  $t_1 \le 15 \text{ ns}$ ,  $t_0 \le 6 \text{ ns}$ ,  $t_p$  (clock) = 25 ns, PRR  $\le 1 \text{ MHz}$ . When testing  $f_{MAX}$  the clock input characteristics are  $V_{gen} = 3 \text{ V}$ ,  $t_1 = t_0 \le 6 \text{ ns}$ ,  $t_p$  (clock)  $\le 25 \text{ ns}$ , and PRR = see table III.
- 2. All diodes are 1N3064, or equivalent.
- 3.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 4.  $R_L = 2 k\Omega \pm 5\%$ .

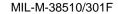
FIGURE 5. Synchronous switching test circuit for device types 01 and 08.

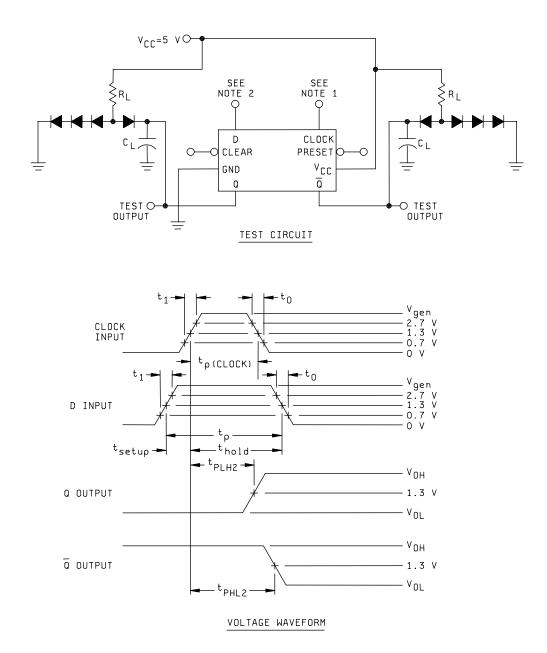


## NOTES:

- 1. Clear and preset inputs dominate regardless of the state of clock or D inputs.
- 2. All diodes are 1N3064, or equivalent.
- 3. Clear or preset input pulse characteristics:  $V_{gen} = 3 V$ ,  $t_0 \le 6 ns$ ,  $t_p$  (clear) =  $t_p$  (preset) = 35 ns, PRR  $\le 1 MHz$ .
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 \ k\Omega \pm 5\%$ .
- 6. When testing clear to output switching, preset input shall have a logical "1" voltage applied. When testing preset to output switching, clear input shall have a logical "1" voltage applied (see table III).

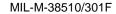
FIGURE 6. <u>Clear and preset switching test circuit and waveforms for device type 02</u>.

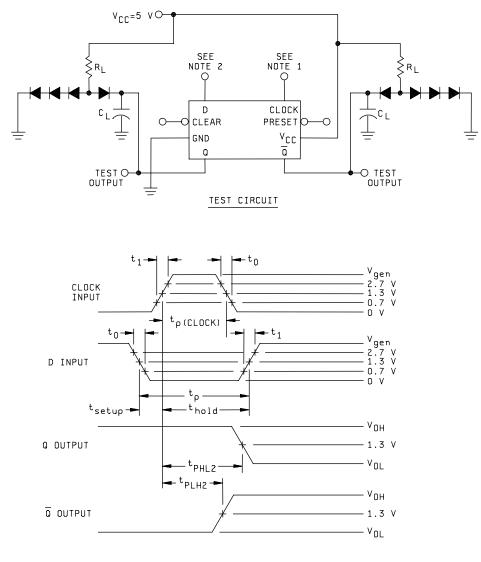




- 1. Clock input pulse has the following characteristics:  $V_{gen} = 3 V$ ,  $t_1 \le 15 ns$ ,  $t_0 \le 6 ns$ ,  $t_p$  (clock) = 30 ns, PRR  $\le 1 MHz$ . When testing  $f_{MAX}$ , PRR = see table III,  $t_p$  (clock)  $\le 30 ns$ , and  $t_0 = t_1 \le 6 ns$ .
- 2. D input has the following characteristics:  $V_{gen} = 3 \text{ V}$ ,  $t_1 \le 15 \text{ ns}$ ,  $t_0 \le 6 \text{ ns}$ ,  $t_{setup} = 20 \text{ ns}$ ,  $t_{hold} = 5 \text{ ns}$ ,  $t_p = 25 \text{ ns}$ , and PRR is 50% of the clock PRR. For  $f_{MAX}$ ,  $t_0 = t_1 \le 6 \text{ ns}$ .
- 3. All diodes are 1N3064, or equivalent.
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 k\Omega \pm 5\%$ .

FIGURE 7. Synchronous switching test circuit (high-level data) for device type 02.



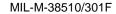


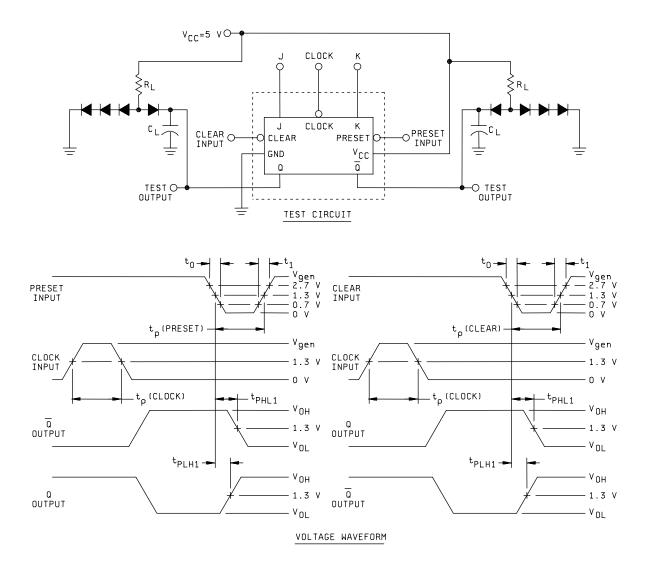
VOLTAGE WAVEFORM

# NOTES:

- 1. Clock input pulse has the following characteristics:  $V_{gen} = 3 V$ ,  $t_1 \le 15 ns$ ,  $t_0 \le 6 ns$ ,  $t_p$  (clock) = 30 ns, PRR  $\le 1$  MHz. 2. D input has the following characteristics:  $V_{gen} = 3 V$ ,  $t_1 \le 15 ns$ ,  $t_0 \le 6 ns$ ,  $t_{setup} = 20 ns$ ,  $t_{hold} = 5 ns$ ,  $t_p = 25 ns$ , and
  - PRR is 50% of the clock PRR.
- 3. All diodes are 1N3064, or equivalent.
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 k\Omega \pm 5\%$ .

FIGURE 8. Synchronous switching test circuit (low-level data) for device type 02.



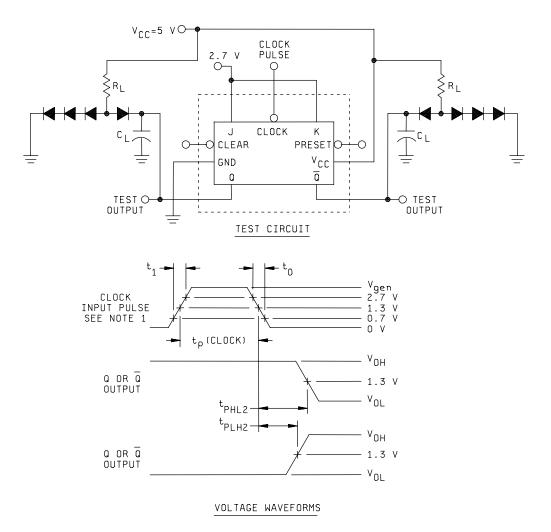


1. Clear or preset inputs dominate regardless of the state of clock or J-K inputs.

2. Clear or preset input has the following characteristics:  $V_{gen} = 3 V$ ,  $t_1 \le 15 ns$ ,  $t_0 \le 6 ns$ ,  $t_p(clear) = t_p(preset) = 30 ns$ , PRR  $\le 1 MHz$ , and  $Z_{out} \approx 50\Omega$ .

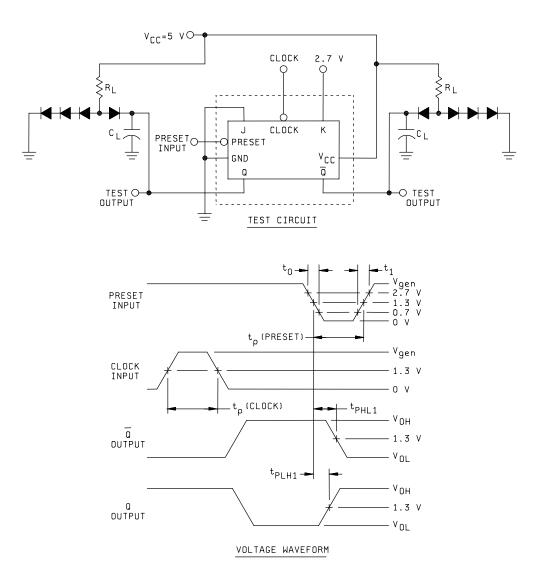
- 3.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 4.  $R_L = 2 k\Omega \pm 5\%$ .
- 5. All diodes are 1N3064, or equivalent.
- 6. When testing clear to output switching, preset input shall have a logical "1" voltage applied. When testing preset to output switching, clear input shall have a logical "1" voltage applied. (see table III).
- 7. Clock input pulse characteristics:  $t_p(clock) \ge 25 \text{ ns}$ ,  $V_{qen} = 3 \text{ V}$ , PRR  $\le 1 \text{ MHz}$ .

FIGURE 9. Clear and preset switching test circuit and waveforms for device types 03, 05, and 10.



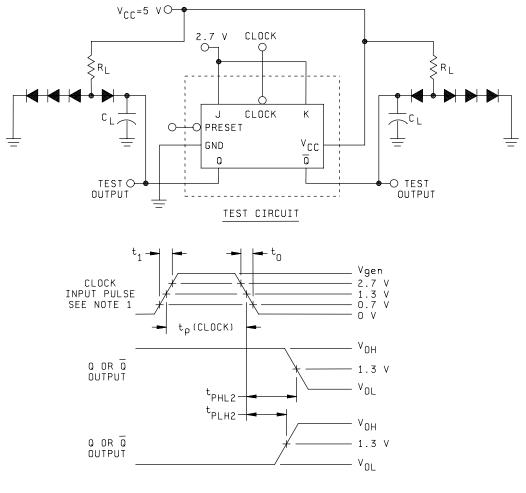
- 1. Clock input characteristics for  $t_{PLH}$ ,  $t_{PHL}$  (clock to output),  $V_{gen} = 3 V$ ,  $t_0 \le 6 ns$ ,  $t_1 \le 15 ns$ ,  $t_p(clock) = 25 ns$ , PRR  $\le 1$  MHz. When testing  $f_{MAX}$  the clock input characteristics are  $V_{gen} = 3 V$ ,  $t_1 = t_0 \le 6 ns$ ,  $t_p(clock) \le 25 ns$ , and PRR = see table III.
- 2. All diodes are 1N3064, or equivalent.
- 3.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 4.  $R_L = 2 k\Omega \pm 5\%$ .

FIGURE 10. Synchronous switching test circuit for device types 03, 05, and 10.



- 1. Preset inputs dominate regardless of the state of clock or J-K inputs.
- 2. Preset input pulse characteristics:  $V_{gen} = 3 V$ ,  $t_0 \le 15 ns$ ,  $t_1 \le 6 ns$ ,  $t_p$  (preset) = 30 ns, PRR  $\le 1 MHz$ .
- 3. All diodes are 1N3064, or equivalent.
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 k\Omega \pm 5\%$ .
- 6. Clock input pulse characteristics: V<sub>gen</sub> = 3 V,  $t_p(clock) \ge 25$  ns, PRR  $\le 1$  MHz.

FIGURE 11. Preset switching test circuit and waveforms for device type 04.

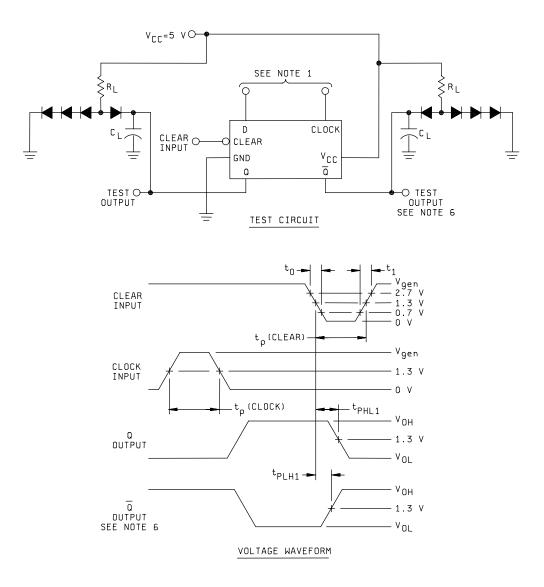


VOLTAGE WAVEFORMS

NOTES:

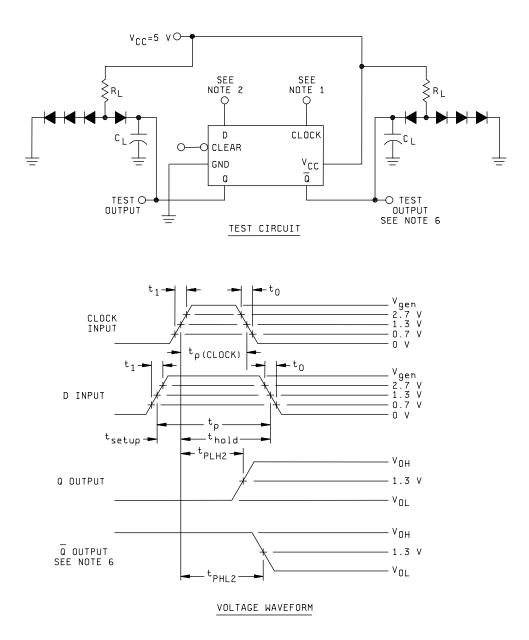
- 1. Clock input characteristics for  $t_{PLH}$ ,  $t_{PHL}$  (clock to output),  $V_{gen} = 3 \text{ V}$ ,  $t_0 \le 6 \text{ ns}$ ,  $t_1 \le 15 \text{ ns}$ ,  $t_p(clock) = 25 \text{ ns}$ , PRR  $\le 1 \text{ MHz}$ . When testing  $f_{MAX}$  the clock input characteristics are  $V_{gen} = 3 \text{ V}$ ,  $t_1 = t_0 \le 6 \text{ ns}$ ,  $t_p$  (clock)  $\le 25 \text{ ns}$ , and PRR = see table III.
- 2. All diodes are 1N3064, or equivalent.
- 3.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 4.  $R_L = 2 k\Omega \pm 5\%$ .

FIGURE 12. Synchronous switching test circuit for device type 04.



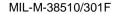
- 1. Clear input dominates regardless of the state of clock or D inputs.
- 2. All diodes are 1N3064, or equivalent.
- 3. Clear input pulse characteristics: V<sub>gen</sub> = 3 V,  $t_0 \le 6$  ns,  $t_1 \le 15$  ns,  $t_p$ (clear) = 35 ns, PRR  $\le 1$  MHz.
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 \ k\Omega \pm 5\%$ .
- 6.  $\overline{Q}$  output applies to device type 07 only.
- 7. Clock input pulse characteristics:  $t_p$  (clock)  $\ge$  25 ns,  $V_{gen}$  = 3 V, PRR  $\le$  1 MHz.

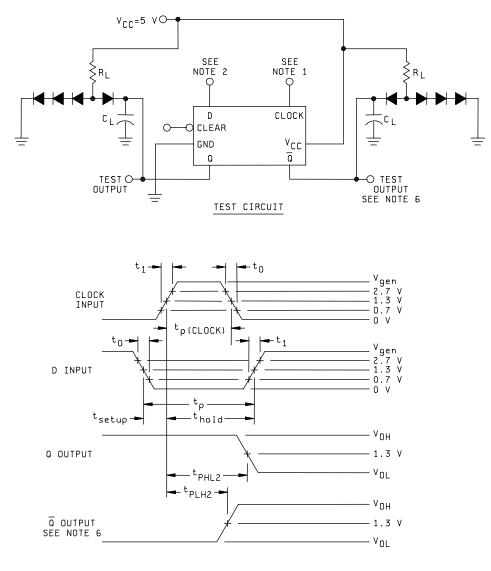
FIGURE 13. Asynchronous switching test circuit for device types 06 and 07.



- 1. Clock input pulse has the following characteristics:  $V_{gen} = 3 V$ ,  $t_1 \le 15 ns$ ,  $t_0 \le 6 ns$ ,  $t_p$  (clock) = 30 ns, and PRR  $\le 1 MHz$ . When testing  $f_{MAX}$ , PRR = see table III,  $t_p$  (clock)  $\le 30 ns$ , and  $t_0 = t_1 \le 6ns$ .
- 2. D input has the following characteristics:  $V_{gen} = 3 V$ ,  $t_1 \le 15 ns$ ,  $t_0 \le 6 ns$ ,  $t_{setup} = 20 ns$ ,  $t_{hold} = 5 ns$ ,  $t_p = 25 ns$ , and PRR is 50% of the clock PRR. For  $f_{MAX}$ ,  $t_0 = t_1 \le 6ns$ .
- 3. All diodes are 1N3064, or equivalent.
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 \ k\Omega \pm 5\%$ .
- 6.  $\overline{Q}$  output applies to device type 07 only.

FIGURE 14. Synchronous switching test circuit (high-level data) for device types 06 and 07.

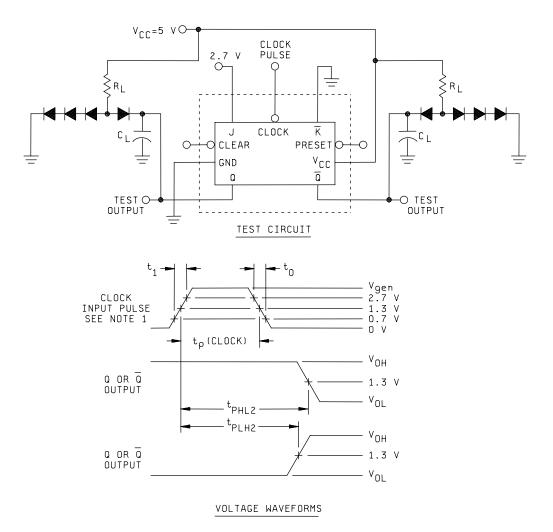






- 1. Clock input pulse has the following characteristics:  $V_{gen}$  = 3 V,  $t_1 \le 15$  ns,  $t_0 \le 6$  ns,  $t_p$  (clock) = 30 ns, and PRR  $\le 1$  MHz.
- 2. D input has the following characteristics:  $V_{gen} = 3 V$ ,  $t_1 \le 15 ns$ ,  $t_0 \le 6 ns$ ,  $t_{setup} = 20 ns$ ,  $t_{hold} = 5 ns$ ,  $t_p = 25 ns$ , and PRR is 50% of the clock PRR.
- 3. All diodes are 1N3064, or equivalent.
- 4.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 5.  $R_L = 2 k\Omega \pm 5\%$ .
- 6.  $\overline{Q}$  output applies to device type 07 only.

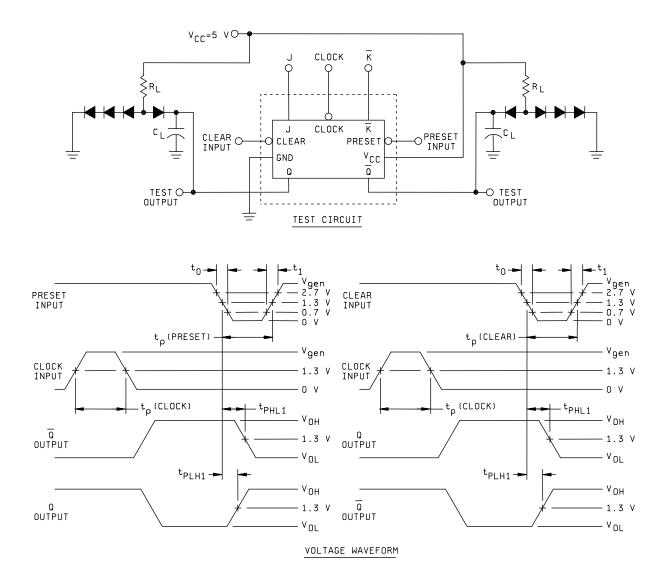
FIGURE 15. Synchronous switching test circuit (low-level data) for device types 06 and 07.



- 1. Clock input characteristics for  $t_{PLH}$ ,  $t_{PHL}$  (clock to output),  $V_{gen} = 3 V$ ,  $t_0 \le 6 ns$ ,  $t_1 \le 15 ns$ ,  $t_p$  (clock) = 25 ns, and PRR  $\le 1 MHz$ . When testing  $f_{MAX}$ , the clock input characteristics are  $V_{gen} = 3 V$ ,  $t_0 = t_1 \le 6ns$ ,  $t_p$  (clock)  $\le 25 ns$ , and PRR = see table III,.
- 2. All diodes are 1N3064, or equivalent.
- 3.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 4.  $R_L = 2 k\Omega \pm 5\%$ .

FIGURE 16. Synchronous switching test circuit for device type 09.





- 1. Clear or preset inputs dominate regardless of the state of clock or  $J-\overline{K}$  inputs.
- 2. Clear or preset input has the following characteristics:  $V_{gen} = 3 \text{ V}$ ,  $t_1 \le 15 \text{ ns}$ ,  $t_0 \le 6 \text{ ns}$ ,  $t_p(clear) = t_p(preset) = 30 \text{ ns}$ , PRR  $\le 1 \text{ MHz}$ , and  $Z_{out} \approx 50\Omega$ .
- 3.  $C_L = 50 \text{ pF} \pm 10\%$  (including jig and probe capacitance).
- 4.  $R_L = 2 k\Omega \pm 5\%$ .
- 5. All diodes are 1N3064, or equivalent.
- 6. When testing clear to output switching, preset input shall have a logical "1" voltage applied. When testing preset to output switching, clear input shall have a logical "1" voltage applied. (see table III).
- 7. Clock input pulse characteristics:  $t_p(clock) \ge 25 \text{ ns}$ ,  $V_{gen} = 3 \text{ V}$ , PRR  $\le 1 \text{ MHz}$ .

FIGURE 17, Clear and preset switching test circuit and waveforms for device type 09.

			Unit			>	-	=	=	=	=	=	=	=	=			=	= :	-			-	-		MA -	=	=	=	=	-		۲ň	=	=	=	=	=	=	=	-		
			hits		Мах							0.4	=	=				-1.5	- :					: =		4	=	-	=	=			07 =	=	=	100	=	=	=	60	60	300	200
			Limits		Min	2.5	=	=	-	-	=															4/	=	-	=	-		:											
			Measured	terminal		ā	'n	Q1	02	02 02	Q2	02	Q2	Q2	a a	۰ C	ð	CLK1	CLR1	K1	CLK2	CLR2	20	57 z	5	۲۲ ۱۱	72	K2	CLK1	CLK2	CLR1	CLKZ	2 -	- 75	K2	K2	J2	K1	1ل	CLR1	CLR2	CLR2	CLN-
	20	2	14	1	۱۱	2.0 V	0.7 V	2.0 V							2.0 V	0.7 V	Z.U V							10~ 1	- 10IIIA	4.5 V 0.4 V			4.5 V		4.5 V	1 5 11	2.7 V					4.5 V	5.5 V	GND			פואר
	19	3	13	2	۱ð	4 mA	4 mA									1 1	4 mA																										
en).	18	4	12	3	Q1			4 mA							4 mA	4 mA																											
V, or op	16	10	11	7	GND	GND	-	-	-	-	=	-	=	-			:	=							-		=	-	=	-			=	=	-	-	-	=	-	-	-		
2.0 V, low ≤ 0.7 V, or open).	14	16	10	11	K2				2.0 V	2.0 V	0.7 V	0.7 V	2.0 V	2.0 V									•	-18mA			4.5 V	0.4 V		4.5 V		4.5 V		4.5 V	2.7 V	5.5 V	4.5 V				4.5 V	4.5 V	
≥ 2.0 V, I	13	8	6	5	Q2						4 mA		4 mA	4 mA																												T	_
be high ≥	12	6	8	9	02 02				4 mA	4 mA		4 mA																														T	
ed may	10	12	7	8	J2				2.0 V	0.7 V	2.0 V	2.0 v	0.7 V	2.0 V								•	-18mA				0.4 V	4.5 V		4.5 V		4.5 V		2.7 V	4.5 V	4.5 V	5.5 V				GND	GND	_
designat	6	14	9	10	CLR2				0.7 V	2.0 V	=	-	=	0.7 V							•	-18mA					3/	4.5 V		3/		0.4 V		GND	GND	GND	GND				2.7 V	5.5 V	_
Terminal conditions (pins not designated may be high ≥	8	13	5	6	CLK2				2.0 V	2/	=	-	=	2.0 V							-18mA						4.5 V	3/		0.4 V		4.5 V		GND	GND	GND	GND				GND	GND	
iditions (	9	20	4	14	V <sub>cc</sub>	4.5 V	-	-	-	=	=	-	=	=			:	=					: =			> c.c	=	-	=	-			=	=	-	=	-	=	=	-	-		_
inal cor	4	6	e	4	К1	2.0 V	2.0 V	0.7 V							2.0 V	2.0 V	0.7 V			-18mA						0.4 V 4.5 V		l	4.5 V		4.5 V	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	4.5 V					5.5 V	4.5 V	4.5 V		1 5 1/	- ^ C - +
Term	З	19	2	13	CLR1	0.7 V	2.0 V	2.0 V							_	2.0 V			-18 mA						2	4.5 V 3/	õl		3/		0.4 V							GND	GND	2.7 V		с V	_
	2	** 18	-			2.0 V	<u>2</u> /	2/							>	2		-18 mA							ò	3/ 4.5 V		Ì	0.4 V		4.5 V		GND	1				GND	GND	GND			
	1	-	Case *	÷.	Test no.	+	2	3	4	5	9	7	8			11	21		14	15	16 1	17	8	19		22		24				87.	30	31	32	33	34	35	36	37	38	39	40
						90				]		20													4	6		<u> </u>				4	2										_
		~	ol 883	meth		3006	-	-	•	-	-	3007	-	-											000	3009	-	-	-	-			- 	-	-	=	-	-	=	-	= :	· ·	
			Symbol			V <sub>OH</sub>						OL						S								IL1			IL3		IL4		Ξ			IH2				IH5		9HI	
			Subgroup			-	Tc = 25°C					>						>											_		_	_	_			_				_			

TABLE III. Group A inspection for device type 01 and 08.

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See footnotes at end of device types 01 and 08.

		Unit			μA	=	=	-	шA	-	=	=	=	'n																																Γ
		Limits		Мах	80	80	400	400	-100	5/	-100	<u>5</u> /	8.0	8.0			See <u>8</u> /	-	=	-	=	=	-	-	-	=	=	-	-	-	-	-	-	-	=	-	=	-	-	=	-	-	=	-	-	
		Lin		Min					-15	2/	-15	<u>5</u> /																																		
		Measured	terminal		CLK1	CLK2	CLK2	CLK1	'n	Q 1	020	Q2	Vcc	Vcc			AII	outputs	=	=	-	-	=	-	=	-	=	-	-			-	-	-	-	-	-	-	-	-	-	-	-	=	-	
20	2	14	-	۲ſ	GND			GND	GND	4.5 V			GND	5.5 V			A		=	-	=	=	в	-	=	=	=	-	-	-	=	-	-	-	=	=	A	-	-	В	-	-	A		-	
19	3	13	2	۰ģ					GND	GND							Н	"	-	=	-	L	=	=	н	=	=	=			-					-	-	-	Г	-	=	-		-	Т	
	4	12	з	ð						2.25 V							Γ		=	=	=	н	=	=	L	=	=	=	-		"	-	-	-	=	=	=	=	т	=	=	=	н	"	Γ	
16	10	11	7	GND	GND	=		-	=	-	=	-	=	=			GND	-	=	=	-	=	=	=	=	=	=	=	-	=	=	-	-	-	=	=	=	-	-	-	=	=	=	=	=	
14	16	10	11	Υ Υ		GND	GND				4.5 V	GND	GND	GND			В		-	=	-	-	=	=	-	=	=	-		A			В		=	-	A	-	-	в	-	-	A		-	
13	8	9	5	Q2								2.25 V					Γ		=		-	-	-	=	-	=	=	-	Н	"	"	L			=	-	=	-	н	-	-	-	"	"	L	
12	9	8	6	02 02							GND	GND			mitted.	nitted.	Н			=			=	-		=			L		н	Н			=	-			L			-	"	"	Т	
6 8 9 10 12 13 14 16	12	7	8	J2		GND	GND				GND	4.5 V	GND	5.5 V	ests are c	sts are or	В	-	-	-	-	-	-	-	-	=	A	-	-	В	-	-	-	-	=	-	A	-	-	в	-	-	A	=	-	
6	14	9	10	CLR2		GND	GND				GND	4.5 V	GND	5.5 V	and V <sub>IC</sub> to	and V IC tests are omitted	в	-	-	=	-	=	=	-	=	=	A	-	-	=	=	-	в	A	=	-	=	-	-	=	-	-	=	=	=	
8	13	5	ი	CLK2		2.7 V	5.5 V				GND	2	GND	2/	+125° C, a	-55° C, ai	в	=	=	=	=	=	=	-	=	=	=	A	в	В	A	в	=	-	A	в	в	A	в	в	A	в	В	A	В	
9	20	4	14	Vcc	5.5 V	-	=	=	-	-	-	-	=	=	cept T <sub>c</sub> =	sept T <sub>c</sub> =	4.5 V	-	-	-	-	-	-	-	-	=	-	-	-	-	-	-	-	-	=	-	=	-	-	-	-	-	=	-	-	
4	9	3	4	ž	GND			GND	4.5 V	GND			GND	GND	oup 1, exo	oup 1, exe	В	-	-	-	-	-	A	-	-	ю	=	-	-	-	=	-	-	-	=	-	A	-	-	в	-	-	A	-	-	
з	19	2	13	CLR1	GND			GND	GND	4.5 V			GND	5.5 V	for subgr	for subgr	В		=	A	-	=	=	=	=	в	=	-						A	=	=	=	=	-	=	-	=		"	-	
2	* 18	1	** 12	CLK1	2.7 V			5.5 V	GND	2/			GND	2/	d limits as	d limits as	В	A	в	в	A	В	в	A	В	=	=	=	-			-	-	-	A	В	в	A	в	В	A	В	В	A	в	!
Cases 1/ *	2, X *	Case *	-	Test no.	41	42	43	44	45	46	47	48	49	50	nditions and	nditions and	51	52	53	54	55	56	57	58	59	60	61	62	63	64	65	99	67	68	69	70	71	72 <u>9/</u>	73	74	75	76	77	78 <u>9</u> /	79	0.00
	Ь		method		3010	-	-	-	3011	=	-	=	3005	3005	Same tests, terminal conditions and limits as for subgroup 1, except $T_c$ = +125° C, and V $_{1C}$ tests are omitted	Same tests, terminal conditions and limits as for subgroup 1, excer	3014	-	=	=	=	=	=	=	=	=	=	=	-	=	-	-	-	-	=	=	=	=	=	=	=	=	=	-	=	
		Symbol			I <sub>H7</sub>		8HI		so				cc	СС	Same tests	Same tests	Truth	table	tests																											
		Subgroup			-	$Tc = 25^{\circ}C$							1				7	6/, 7/																												0 51 71

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See footnotes at end of device types 01 and 08.

			Unit			MHz	-	-	-	su	-	=	=	-	-	-	-	-	-	-	-	MHz "	su	=	=	-	
			its		Мах					21	21	28	28	22	-	=	-	30	=	=			32	40	32	42	
			Limits		Min	25	=	=	=	5	=	=	=		=	=	=	=	=	=		25	5	5	5	5	
			Measured	terminal		6 6	β	°0	Q2	CLR2 to 02	CLR1 to Q1	CLR1 to Q1	CLR2 to Q2	CLK2 to Q2	CLK2 to $\bar{\rm O2}$	CLK1 to Q1	CLK1 to Q1	CLK1 to Q1	CLK1 to Q1	CLK2 to 02	CLK2 to Q2						
	20	2	14	٢	۱۱	2.7 V	2.7 V				2.7 V	2.7 V				2.7 V	2.7 V	2.7 V	2.7 V								
	19	3	13	2	ğ		OUT				OUT						OUT	OUT									
en).	18	4	12	3	Q1	OUT						OUT				OUT			OUT								
/, or op(	16	10	11	7	GND	GND	-	-	=	-	=	=	=		-	-	-	=	=	-							
v ≤ 0.7 \	14	16	10	11	K2			2.7 V	2.7 V	GND			GND	2.7 V	2.7 V					2.7 V	2.7 V						
.0 V, lov	13	8	6	5	Q2				OUT				OUT	OUT							OUT						
Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open)	12	6	8	6	ō2			OUT		OUT			-	-	OUT					OUT	-		S°C				
nay be	0	12	7	8	JZ			2.7 V 0	2.7 V				2.7 V	2.7 V	2.7 V 0					2.7 V 0	2.7 V		Γ <sub>C</sub> = +12!				
gnated r	1																						except 7				
ot desiç	6	14	9		2 CLR2			2.7 V	2.7 V	Z			NI	2.7 V	2.7 V					2.7 V	2.7 V		group 9,				ç
(pins n	8	13	2	6	CLK2			Z	N	Z			Z	N	Z					Z	N		s for sub				Γ <sub>C</sub> = -55°
nditions	9	20	4	14	V <sub>cc</sub>	5.0 V	-	-	=	-	-			=	=	=	-	=	=	-			ditions a				except 7
ninal coi	4	9	с	4	К1	2.7 V	2.7 V				GND	GND				2.7 V	-	=	=				ninal con				froup 10,
Tern	3	19	2	13	CLR1	2.7 V	2.7 V				N	N				2.7 V	=	=	=				and tern				s for subg
	2	18	ſ	** 12	CLK1	Z	z				z	N				Z	=	=	=				ame tests				d limits a:
	Cases 1/ *	2, X **	Case *	**	Test no.	80	81	82	83	84	85	86	87	88	89	06	91	92	93	94	95	66 - 96	100 - 101 Same tests and terminal conditions as for subgroup 9, except $T_c = +125^{\circ}C$	102 - 103	104 - 107	108 - 111	Same tests, terminal conditions, and limits as for subgroup 10, except $T_{\rm C}$ = -55°C
		MIL-STD-	883	method		Fig. 4	=	=	-	3003	Fig.4	-	-	3003	Fig.5	-	=	3003	Fig.5	=	-	Fig. 4	3003 Fig. 4	3003 Fia. 4	3003 Fia. 5	3003 Fia. 5	ts, terminal c
			Symbol			f <sub>MAX</sub>	<u>10/</u>			PLH1		PHL1		PLH2				PHL2				f <sub>MAX</sub> 10/	PLH1	PHL1	PLH2	PHL2	Same tes
			Subgroup			6	$Tc = 25^{\circ}C$					t		t								10 Tc = +125∘C					11

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TABLE III. <u>Group A inspection for device type 01 and 08</u> – Continued.

\* Terminal numbers for device type 01.
 \*\* Terminal numbers for device type 08.
 1/ Case X and 2 pins not referenced are NC.
 2/
 --- 2.5 V minumum/5.5 V maximum

<u>3</u>/

2.5 V minumum/5.5 V maximum

> 0

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Terminal conditions (pins not designated may be high  $\ge 2.0$  V, low  $\le 0.7$  V, or open). TABLE III. Group A inspection for device type 01 and 08 – Continued.

 $\underline{4}$ / I<sub>IL</sub> limits in mA are as follows:

H <sub>L1</sub> A B A B075/25003/30	Min/Max limits for C 3011/25	:кт D 12/36	Min/Max limits for CKT	A B C	03/3011/25	
//Max limits for C C 11/25	КТ D 12/36			ш	12/36	

			IVIII / IVIAX III IIIS IUI CNI		
	A	В	С	D	ш
	075/250	075/25003/3011/25	11/25	12/36	12/36
		Min/	Min/Max limits for CKT	CKT	
<sub>IL3</sub>	۲	В	ပ	D	ш
	15/60	06/60	15/56	29/72	24/72
		Min/	Min/Max limits for CKT	СКТ	
I <sub>IL4</sub>	A	В	C	D	Ш
	16/70	06/70	29/65	20/80	12/72

	ш	12/72	
CKT	D	20/80	
Min/Max limits for CKT	ပ	29/65	
Min/I	В	06/70	
	A	16/70	
	F4		

 $\overline{5}$ / los limits are as follows:

7.5/-50	15/-100
CKT's A, B, C	CKTD
Test nos. 46 and 48:	

 $\overline{6}$ / Input voltages shown are A = 2.0 volts minimum and B = 0.7 volts maximum.

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 $\overline{Z}$ / Tests shall be performed in sequence, attributes data only.

<u>8/</u> Output voltages shall be  $H \ge 1.5$  V and L < 1.5 V.

 $\underline{9}$  These tests may be performed as shown in table III or alternately as follows:

٢	A	=	=	=	=	=
å	т				т	н
g	Γ	Н	Н	Н	Γ	Γ
GND	GND	"	H		H	=
Υ Υ	A					=
02 0	L	Γ	ſ	т	н	т
_ Q2	Н	Н	Н	Γ	Γ	L
J2	A	=	=	=	=	=
CLR2	A	=	=	=	=	=
CLK2	В	В	۲	В	В	A
V <sub>cc</sub>	4.5 V	=	=	=	=	H
전	A	=	=	=	=	=
CLR1	A	=	=	=	=	=
CLK1	۲	В	В	۲	В	В
Test no.	72A	72B	72C	78A	78B	78C

10/ f<sub>wwx</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

		Unit		>	=	-	-	-	=	=	=	=	=	=	=	=	-	-	=	=	=	-	-	-	-	=	=	mA	=	=	=	=	=
		ts	Мах									0.4	=	=	=		=	=	=	-1.5	=	=	-	=	=	=	=	3/	=	=	=	=	=
		Limits	Min	2.5	=	-	-	-	=	=	=																	3/	=	-	=	-	=
		Measured terminal	1	۱ġ	ð	ð	ā'	Q2	02 02	°.	Q2	۵1 ۵	ā	ıą	6 b	Q2	02 02	02 02	Q2	CLR1	D1	CLK1	PR1	PR2	CLK2	D2	CLR2	D1	D2	CLK1	PR1	PR2	CLK2
	20	14	V <sub>cc</sub>	4.5 V	=	-	=	-	=	=	=	=	=	=	=	=	=	=	=		=	-	-	-	=	=	=	5.5 V	=	=	-	-	=
	19	13	CLR2					2.0 V	0.7 V	2.0 V	2.0 V					2.0 V	=	=	0.7 V								-18 mA		4.5 V			GND	4.5 V
(C	18	12	D2					2.0 V	2.0 V	0.7 V	2.0 V					0.7 V	2.0 V	=	=							-18 mA	-		0.4 V			GND	GND
or oper	16	11	CLK2					GND		2/	2/							GND	GND						-18 mA	`			4.5 V				0.4 V
≤ 0.7 V,	14	10						-		_														mA	-18				GND 4.				
V, Iow	÷	-	PR2						2.0 V	-	" Y					A 2.0 V	2.0 V	0.7 V	A 2.0 V					-18					ß			0.4 V	GND
<u>uevice</u> 3h ≥ 2.0	13	6	Q2					4 mA	4	4	4 mA					4 m A	-		4 mA													_	
y be hig	12	∞	0 <sup>-</sup> 0						4 mA	4 mA							4 mA	4 mA															
ated ma	10	2	GND	GND	-	-	-	-	=	-	-	=	=	=	-		=	-	-		=	-	-	-	-	=	=	=	=	-	-	-	-
designa	6	9	۱ð	4 mA			4 mA						4 mA	4 mA																			
Terminal conditions (pins not designated may be high ≥ 2.0 V, low ≤ 0.7 V, or open).	ω	5	a1		4 mA	4 mA						4 mA			4 mA																		
ditions (	9	4	PR1	2.0 V	0.7 V	2.0 V	2.0 V					2.0 V	2.0 V	0.7 V	2.0 V								-18 mA					GND		GND	0.4 V	_	
inal con	4	ю	CLK1	GND	GND		2/						2/	GND	GND							-18 mA						4.5 V			GND		
Term	е К	7	5	2.0 V	=	-	0.7 V					0.7 V	2.0 V	=	=						-18 mA	`1						0.4 V			GND	_	
	2	-	CLR1	0.7 V 2	2.0 V	_	-					2.0 V C	=	=	0.7 V					-18 mA	-							4.5 V C			GND	_	
		s D			2.															-18													_
	Cases <u>1</u> 2, X	Cases A,B,C,D	Test no.	~	2	e	4	2	9	7	8	6	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26	27	28	29	30
	MIL-STD-	883 method		3006	-	-	-	-	-	-	-	3007	-	-	-	-	-	-	-									3009	-	-	-	-	=
		Symbol		V <sub>он</sub>								OL								IC								IL2		IL4			
		Subgroup		-	Tc = 25°C							>								>								_		_			

TABLE III. Group A inspection for device type 02.

See footnotes at end of device type 02.

		Unit		шA	шA	μA	=	=		=	=	=	=	=	=	=	=	-	=	=	-	шA	-	=	-	-	=									
ĺ		its	Max	3/	<u>ري</u>	20	20	100	100	40	=	=	-	200	=	=	=	60	60	300	300	-100	-	=	=	8.0	8.0			See <u>7</u> /	=	=	=	-	=	-
		Limits	Min	3/	3/																	-15	-	=	=											
		Measured terminal	<u> </u>	CLR1	CLR2	5	D2	D2	D1	CLK1	PR1	PR2	CLK2	CLK2	PR2	PR1	CLK1	CLR1	CLR2	CLR2	CLR1	۱۶	ø	Q2	02 02	V <sub>cc</sub>	Vcc			All outputs	=	=	=	=	-	=
	20	14	Vcc	5.5 V	-	=	=	=	=	=	=	=	=	=	=	=	=	=	=	=	=	=	=	=	=	-	=			4.5 V	=	=	=		=	=
	19	13	CLR2		0.4 V		GND	GND				4.5 V	GND	GND	4.5 V				2.7 V	5.5 V					GND	5.5 V	GND			В	В	A	=	-	в	В
en).	18	12	D2		4.5 V		2.7 V	5.5 V				4.5 V	4.5 V	4.5 V	4.5 V				GND	GND						GND	GND			В	=	=	=		-	A
V, or op	16	11	CLK2		4.5 V		4.5 V	4.5 V				4/	2.7 V	5.5 V	4/				4/	4						GND	GND			В	=	-	=	A	-	-
iditions (pins not designated may be high $\geq 2.0$ V, low $\leq 0.7$ V, or open)	14	10	PR2		GND		4.5 V	4.5 V				2.7 V	4.5 V	4.5 V	5.5 V				4.5 V	4.5 V				GND		GND	5.5 V			В	A	A	В		=	=
≥ 2.0 V,	13	6	Q2																					GND						т	_	Γ	г		-	=
be high	12	8	02 02																						GND			nitted.	ted.	н			L	L	н	т
ited may	10	7	GND	GND	-	=	=	=	=	=	=	=	=	-	=	=	=	-	=	-	=	-	-	=	-	-	=	+125°C and V <sub>IC</sub> tests are omitted.	= -55°C and V <sub>IC</sub> tests are omitted.	GND	=	=	=	-	-	-
designa	o	9	'n																			GND						and V <sub>IC</sub> te:	d V <sub>IC</sub> test	т	=	=	_	_	т	т
pins not	ø	5	6 F																				GND					+125°C a	-55°C an	н	L	L	н	"	=	=
iditions (	9	4	PR1	GND		4.5 V			4.5 V	4.5 V	2.7 V					5.5 V	4.5 V	4.5 V			4.5 V		GND			GND	5.5 V	ept T <sub>c</sub> =	ept T <sub>c</sub>	В					-	=
l erminal cor	4	ო	CLK1	4.5 V		4.5 V			4.5 V	2.7 V	4/					4/	5.5 V	4/			4/					GND	GND	oup 1, exe	oup 1, exe	В	=	=	=	A	-	=
	ო	7	Б	4.5 V		2.7 V				4.5 V	4.5 V					4.5 V	4.5 V	GND			GND					GND		for subgro	for subgro	В	=	=	=		-	A
	2	-	CLR1	0.4 V		GND					4.5 V					4.5 V		2.7 V			5.5 V	GND					GND	and limits as for subgroup 1, except $T_{c}$ =	I limits as	В	в	A	=	-	в	в
	Cases <u>1</u> / 2, X	Cases A,B,C,D			32		34	35	36			39	40	41	42		44		46	47	48		50	51	52		54	ditions, and	ditions, and	55	56	57	58	59	60	61
	MIL-STD-		<u> </u>	3009	-	3010	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	3011	-	-	=	3005	3005	Same tests, terminal conditions,	terminal con	3014	table " 56 B " "	-	-	-	-	=
	Ē	Symbol		l <sub>IL5</sub>		H		IH2		IH3				IH4				IH5		9HI		so				8		ame tests, t	ame tests, i	Truth	table	tests				
		Subgroup		-	Tc = 25°C																	<u> </u>						2 Si	о З	7 <u>5</u> /, <u>6</u> /	Tc = 25°C					

TABLE III. <u>Group A inspection for device type 02</u> - Continued.

MIL-M-38510/301F

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See footnotes at end of device type 02.

	Unit																							MHz	-	=	=	ns	-	=	=	=	=	-	-	-	=	-	=	-	-	-	=
	Limits	Max	See 7/	-		-	-	-	=	=	=	= :	-	-	-	-	-	=	-	-	=	=						30	-	-	=	46	-	-	-	30	-	=	-	46	=	-	=
	C	Min																						20	-	=	=	5	-	=	-	=	-	-	-	-	=	-	=	=	-	-	-
	Measured terminal		All outputs	=		=	= :	=	-	=	=	= :		= :	=	-		-	=	=	-	=		a1	۱ð	18 18	Q2	PR2 to Q2	CLR2 to 02	CLR1 to G1	<b>PR1 TO Q1</b>	CLR1 to Q1	PR1 to 01	PR2 to 02	CLR2 to Q2	CLK2 to Q2	CLK2 to 02	CLK1 to Q1	CLK1 to 01	CLK1 to 01	CLK1 to Q1	CLK2 to 02	CLK2 to Q2
20	14	V <sub>cc</sub>	4.5 V	-		-	-	-	=	=	=	-	-	-	-	-	-	=	-		=	-		5.0 V	-	=	=	=		-		=	-	-	-	-	-	-	=	-	-	-	-
19	13	CLR2	В	A		-		-	=	=	в	- :	-	A	-	=	-	-	В	A	-	-				2.7 V	2.7 V	Z	Z					NI	Z	2.7 V	2.7 V					2.7 V	2.7 V
18	12	D2	A	=		-	=	В	=	=	A	В	-	-	A	-		-	-	"	В	В				Z	Z									N	N					N	N
16	11	CLK2	A	-		=	ш	в	A	=	=	-	-	=	B	A	-	=	=		=	=				z	z									Z	Z					z	Z
14	10	PR2	A	A	Ъ	A	-	=	=	в	=	= -	A	-	-	=	в	A	=	=	В	A				2.7 V	2.7 V	Z	Z					Z	Z	2.7 V	2.7 V					2.7 V	2.7 V
13	6	Q2			т	=	-	=	_	т	=	= .		-	= ;	т	=	=		L	т	т					OUT	OUT							OUT	OUT							OUT
12	8	_02	т	т	;	-		-	т	_	т		-	-	= .		-	-	т	т		-				OUT			OUT					OUT			OUT					OUT	
10	7	GND	GND	-		=	-	=	=	=	=	= :	-	-	-	=	=	=	=	=	=			GND	-	-	=	=	-	-	=	=	-	-	=	=	-	=	=	-	=	=	=
ი	9	'n	т	т	:	-	-	=	т	L	т	= :	-	-	= .	L	-	=	т	н	_	_			OUT					OUT			OUT						OUT	OUT			
ø	5	Q1			т	=	-	=		т	=	= .	:	-	-	т	-	=		L	т	т		OUT							OUT	OUT						OUT			OUT		
9	4	PR1	A	A	В	A	-	=	=	в	=	= -	A	-	-	-	В	A	=		в	A		2.7 V	2.7 V					z	z	Z	Z					2.7 V	2.7 V	2.7 V	2.7 V		
4	3	CLK1	A	=	= :	=	ш	в	A	=	=	-		=	ш	A	-	=	=		=	=		N	Z													Z	Z	z	Z		
ო	2	D1	A	=		=	=	в	=	=	A	В	-	-	A	=	=	=	=	=	в	В	-55°C	N	Z													Z	≥	z	Z		
7	-	CLR1	в	A		-		=	=	=	в	= :		A	-	=	-	-	в	A	-	=	and $T_c =$	2.7 V	2.7 V					z	Z	Z	Z					2.7 V	2.7 V	2.7 V	2.7 V		
Cases <u>1</u> / 2, X	Cases A,B,C,D	Test no.	62	63	64	65	99	67	68	69	70	71	72	73	74	75	76	77	78	79	80	81	<sub>C</sub> = +125°C	82	83	84	85	86	87	88	89	06	91	92	93	94	95	96	97	98	66	100	101
MIL-STD-	883 method		3014	=		=		=		=	-			=		-	=	-	-	=	-	-	Repeat subgroup 7 at $T_c$ = +125°C and $T_c$ = -55°C	Fig. 8	7	=	-	3003	Fig. 6	=	=	=	-	=	=	3003 Fig. 7	3003 Fig. 8						
	Symbol		Truth	table	tests																		Repeat su	f <sub>MAX</sub>				PLH1				PHL1				PLH2				PHL2			-
	Subgroup		7 <u>5</u> /, <u>6</u> /	_c = 25°C																			8 <u>4</u> /, <u>5</u> / F	-	Tc = 28°C			1				1				1				1			

See footnotes at end of device type 02.

		Unit		MHz	su	=	=	-	=	=	=	=	=	=	
		Limits	Max		39	65	68				69				
		ŗ	Min	20	5	=									
		Measured terminal													
	20	14	V <sub>cc</sub>												
	19	13	CLR2												
en).	18	12	D2												
I erminal conditions (pins not designated may be high $\geq 2.0$ V, low $\leq 0.7$ V, or open).	16	11	CLK2												
10W ≤ U.7	14	10	PR2												
≥ ∠.U V,	13	6	Q2												
pe nign	12	ω	°2					.125°C							
tea may	10	7	GND					ept $T_c = +$							
designa	6	9	٩'n					up 9, exc							
pins not	8	5	6					or subgro							= -55°C
) SUOIIDL	9	4	PR1					litions as f							⊧xcept T <sub>C</sub> :
ninal col	4	ю	CLK1					ninal conc							roup 10, ∈
liai	з	2	5					s and tern							for subg
	2	-	CLR1					Same tests and terminal conditions as for subgroup 9, except $T_{\rm C}$ = +125°C							d limits as
	Cases <u>1</u> / 2, X	Cases A,B,C,D	Test no.	102-105	106-109	110-113	114	115 S	116	117	118	119	120	121	nditions, an
	MIL-STD-	883 method	L	Fig. 8	3003 Fig.6	3003 Fig. 6	3003 Fig. 7	3003 Fig. 8	3003 Fig. 7	3003 Fig. 8	3003 Fig. 7	3003 Fig. 8	3003 Fig. 7	3003 Fig. 8	Same tests, terminal conditions, and limits as for subgroup 10, except $T_{\rm C}$ = -55°C
	-	Symbol		f <sub>MAX</sub> /	PLH1 3	PHL1 30	PLH2 30	õ	ñ	ñ	PHL2 3(		Ś	ñ	ame tests
		Subgroup Symbol		10	<u> </u>	<u> </u>									11 S
		SL		œ	t	t	t				t				Ш

1/ Case X and 2 pins not referenced are NC.

- - - 2.5 V minumum/5.5 V maximum

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۸ 0

I<sub>IL</sub> limits in mA are as follows:

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-.135/-.370 ш ш Min/Max limits for CKT Min/Max limits for CKT -.095/-.210 -.097/-.207 ۵ ပ -.030/-.300 മ മ -.075/-.250 ∢ ∢ 112 ||L4

-160/-.400

ш

		150/500	060/700	160/400	160/400 for	120/360	320/800
		for tests 27,		for tests 27,	tests 27, 30	for tests 27,	(III)
		30		30	355/759 for	30	
		200/800		350/760	tests 28, 29	280/760	
		for tests 28,		for tests 28,		for tests 28,	
		29		29		29	
L				Min/Max	Min/Max limits for CKT		
	lıcs	A	В	C	D	Е	H
		200/800	060/700	350/760	480/-1.200	280/760	480/-1.200

>0 4

- 5/ Input voltages shown are A = 2.0 volts minimum and B = 0.7 volt maximum. 6/ Tests shall be performed in sequence, attributes data only. 7/ Output voltages shall be H  $\ge$  1.5 V and L < 1.5 V. 8/ f<sub>MAX</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

TABLE III. Group A inspection for device type 02 - Continued.

		Unit		>	=	=	=	=	=	-	=	=	=	=	=	-	=	=	=	=	-	-	=	mA		=	=	=	=	-	Au	=	=	=	=	=	-	=
		its	Max							0.4	=	=	-	=	=	-1.5	=	=	=	=	-	=	=	4		=	=	=	=	=	20	=	=	=	100	=	-	=
		Limits	Min	2.5	=	-	-	-	=															4		-	=	=	-	-								
		Measured terminal		Q1	ā1	a1	_ 02	Q2	Q2	_ Q2	02	Q2	ā1	۱ð	9 1	CLK1	K1	11	PR1	PR2	J2	K2	CLK2	5 5	J2	22	20	CLX2		PR2	K1	١١	J2	K2	K2	J2	۲Ļ	K1
	20	14	V <sub>oc</sub>	4.5 V	=	-	=	-	=	-	=	=	=	-	-	-	=	=	-	=	-	-	=	5.5 V		-	=	=	=	-	-	-	-	-	-	=	=	=
	19	13	CLK2				2/	2/	2.0 V	2.0 V	2/	2/											-18 mA			V C.4	10			4.5 V		l	2/	GND	GND	2/		
n).	18	12	K2				2.0 V	0.7 V	2.0 V	2.0 V	0.7 V	2.0 V										-18 mA				0.4 V		, , ,		4.5 V		l	GND	2.7 V	5.5 V	GND		
, or ope	16	11	J2				0.7 V	2.0 V		-		0.7 V									-18 mA	•				GND				4.5 V	-		2.7 V			5.5 V		
Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open)	14	10	PR2				2.0 V 0			0.7 V	2.0 V	2.0 V 0								-18 mA	4					3/1	_			0.4 V 4	_		4.5 V 2					
0 V, lov	13		Q2 F				2			0	7	4 m A 2								<u>-</u>							1			0		ŀ	4	0	0	4		
high ≥ 2	2	8	0 0 0 0				4 mA	4	4	4 mA	4 mA	4							_			_			+	+	T											
may be	` 0	7	GND	GND		-	" 4	-	=	" 4	4	-		-	=	-		=	=	-		=	-				=	_	-	-	_	_	=	_			=	-
ignated	-				- YU	-	_	-	-	-	-	-			-	-	-	_	-	-	-	-	-			-	-	-	-	-			-		_		-	-
not desi	6	9	۱ġ		4 mA	A							4 mA	4 mA	⊲																							
s (pins	8	5	ð	·4 mA		4 mA									4 mA				∢							_												
conditior	9	4	PR1	0.7 V	2.0 V	2.0 V							0.7 V	2.0 V	2.0 V			/	-18 mA					3/	4.5 V			76	2 10		GND	4.5 V					4.5 V	GND
rminal c	4	ε	۲ſ	2.0 V	0.7 V	2.0 V							2.0 V	2.0 V	0.7 V			-18 mA						GND	0.4 V			4 5 V	2.4	2	GND	2.7 V					5.5 V	GND
Te	3	2	¥	2.0 V	2.0 V	0.7 V							2.0 V	0.7 V	2.0 V		-18 mA						,	0.4 \	4.5 V			45 \		> ;	2.7 V	GND					GND	5.5 V
	2	<del>.</del>	CLK1	2.0 V	2/	2/							2.0 V	2/	2/	-18 mA								4.5 V	<u>%</u>			041	1.1	> ?	GND	2/					2/	GND
	Cases <u>1</u> / 2, X	Cases A,B,C,D	Test no.	1	2	с	4	5	9	7	∞	6	10	11	12	13	14	15	16	17	18	19	20	21	52 8	23	25	22 96	27	28	29	30	31	32	33	34	35	36
	MIL-STD-	883 method		3006	=	-	=	-	-	3007	=	=	=	=	-		<u> </u>							3009			-	-	=	=	3010	=	=	-	-	l =	=	=
		Symbol		V <sub>OH</sub>						OL						С								IL1				<b>L</b> 3		IL4	H1				IH2			
		Subgroup		-	Tc = 25°C					>						>															<u> </u>							

TABLE III. Group A inspection for device type 04.

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See footnotes at end of device type 04.

		Unit	~	Ρή		-						HII -	=			-	-			<u> 6</u>																											
		Limits	n Max	60	60	300	300	80	80	400		- 100 6/		-100		8.0	8.0			See 5	=	=	=	=	-	=	=	=	=	-		=	=	=	=	=	=	=	-	=	=	=		=	=	=	-
_			Min							-	15	9	δi -	-12	<u>6</u> /						6				_		_													_							
		Measured terminal		PR1	PR2	PR2	PR1	CLK1	CLK2	CLK2	CLK1	3	δg	62	02 02	V <sub>cc</sub>	V <sub>cc</sub>			AII	outputs	=	-	-	=	-	=	=	=	-		-	-	=	=	=	-	=	-	-	=	-	=	-	-	-	=
0	20	14	V <sub>cc</sub>	5.5 V	=	=	=	=				=	=			=	=			4.5 V	=	=	=	=	=	=	=	=	=	-		=	=	=	=	=	=	=	=	=	=	=		=	=	=	=
	19	13	CLK2		GND	GND			2.7 <	5.5 V				ò	2/	2/	5.5 V			В	=	=	-	=	-	-	=	-	-	=	۲u	ם מ	⊲	c ۵	) =	=	A	в	В	٨	в	В	A	В	в	A	ш
en).	18	12	K2		GND	GND			GND	GND					4.5 V	5.5 V	5.5 V			В	=	=	=	=	-	=	=	=	A	=		6	<u>ء</u>	=	=	=	=	=	A	=	=	в	=	=	A	=	-
l erminal conditions (pins not designated may be nign ≥ ∠.∪ v, low ≤ ∪./ v, or open).	16	11	J2		4.5 V	4.5 V			GND	GND		Ì			GND	GND	5.5 V			В	=	=	=	=	=	-	=	=	=	=		<	₹ =	=	в	=	=	=	A	=	=	в		=	A	=	=
N	14	10	PR2			5.5 V			GND	GND				GND	4.5 V	5.5 V				В	=	=	=	=	=	=	=	=	=	A		=	=	=	в	A	=	=	-	=	=	=		=	=	=	=
z.U V, IU	13	6	Q2			2/			-				_	GND						н	=	=	=	=	=	=	=	=	=	=		=	=	Т	: =	=	=	=	-	=		=		=	=	=	т
	12	8	02 02												GND <u>6</u> / 0			ed	-	L	=	=	-	=	=	=	=	=	=	=		c =	=	_	1 =	=	=	-	-	-	т	-	=	=	=	=	_
i iiiay ut	10	7	GND	GND	=	=	-	=				-	-			=	=	are omitt	re omitteo	GND	=	=	=	=	=	=	=	=	=	=		=	=	=	=	=	-	=	-	=	=	=		=	=	=	=
olyl later	6	9	٩' ۵	0					_			GND 6/	ة 1					V <sub>IC</sub> tests	IC tests a	L O	=	=	=	=	Н	=	=	_	=	=		=	-	=	=	=	-	=	-	=	т	-		=	=	=	
	8	5	ð	<u>5</u> /			<u>5</u> /			-	2	GND GND						25°C and	°C and V	Т	=	-	=	-		=	=	т	=	=		_		=	=	=	-	-	_	-		-		=	-	=	т
	9	4	PR1 0					GND	_	!	GND	_				5.5 V	P	$T_{c} = +12$	: T <sub>c</sub> = -55	В	=		_	=	=	-	_		В	=						A			_				_				_
				V 2.7 V				_		-	-	-	-				V GN	1, except	1, except			-	4			-	-					-	-	-	-		-	-		-	-		-	-	-	-	-
	4	3	۲	D 4.5 V				D GND	_	_	C GND	UD GND	_				V 5.5 V	ubgroup	ubgroup	В	-	=	=	-	-	A	-	-	В	-		-	-	-	-	=	-	=	A	-	-	В		-	A	=	-
	33	2	1 K1	O GND			O GND	_	+	-	/ GND	4 5 V	2			5.5 V	/ 5.5	ts as for s	ts as for s	A	=	=	=	=	=	В	=	=	=	=		=	=	=	=	=	=	=	A	=	=	В	=	=	A	=	-
	/ 2	-	. CLK1	GND			GND	2.7 V		1	5.5 V	16	Ĩ			2/	5.5 \	, and limi	, and limi	В	A	В	В	A	B	В	A	В	=	-		-	=	=	=	=	A	Ш	B	4	В	В	A	В	В	A	۵
	Cases <u>1</u> / 2, X	Cases A,B,C,D	Test no.	37	38	39	40	41	42	43	44	46	ţ	47	48	49	50	onditions,	onditions,	51	52	53	54	55	56	57	58	59	60	61	62	00	04 65	S S	67	68	69	20	71	72	73	74	75	76	77	78	79
ſ	MIL-STD-	883 method	<u>.</u>	3010	=	-	-	-			= 001		-			3005	3005	terminal c	terminal c	3014	-	=	=	-	=	-	=	=	-	-		-	-	=	=	-	-	=	-	-	-	-	=	=	=		-
$\left  \right $	Z	Symbol		I <sub>H5</sub>		9HI		1H7	+	H8	+	so				8		Same tests, terminal conditions, and limits as for subgroup 1, except $T_{C}$ = +125°C and $V_{1C}$ tests are omitted	Same tests, terminal conditions, and limits as for subgroup 1, except $T_{\rm C}$ = -55°C and $V_{\rm IC}$ tests are omitted	Truth	table	tests																									
		Subgroup S		-	$Tc = 25^{\circ}C$	]													3 3	7 <u>7</u> /, <u>8</u> / 1																											

TABLE III. Group A inspection for device type 04 - Continued.

See footnotes at end of device type 04.

		Unit		MHz	-	=	=	ns	=	=	=	-	=	=	=	-	=	-	=	MHz	su	-	=		-				
			Max	F				21	21	28	=	22	=	=	=	30	=	=	=		32	40	32		42				
		Limits	Min	25	-	-	=	5	-	-	=	-	=	-	=	-	-	-	=	25	5	=	=		=	-			
		ured inal		1	1	5	5	o Q2	o Q1	۱g	o 02	to Q2	to O2	to Q'	to Q1	to Q1	to Q	to O2	to Q2							-			
		Measured terminal	1	a 1	٩١	°9'	Q2	PR2 to Q2	PR1 t	PR1 to 01	PR2 to 02	CLK2 to Q2	CLK2 to O2	CLK1 to 01	CLK1 to Q1	CLK1 to Q1	CLK1 to O1	CLK2 to 02	CLK2 to Q2										
	20	14	V <sub>cc</sub>	5.0 V	-	-	=	-	-	-	-	-	-	-	=	-	=	-	=										
	19	13	CLK2			N	IN	IN			N	N	N					N	IN										
en).	18	12	K2			2.7 V	2.7 V	2.7 V			2.7 V	2.7 V	2.7 V					2.7 V	2.7 V										
<u>e 04</u> - Continued. 2.0 V, Iow ≤ 0.7 V, or open)	16	11	J2			2.7 V	2.7 V	GND			GND	2.7 V	2.7 V					2.7 V	2.7 V										
Group A inspection for device type 04 - Continued ins not designated may be high $\ge 2.0 \text{ V}$ , low $\le 0.7 \text{ V}$	14	10	PR2			2.7 V	2.7 V	N			N	2.7 V	2.7 V					2.7 V	2.7 V										
<u>&gt;e 04</u> - 0 ≥ 2.0 V, I	13	ი	Q2				OUT	OUT				OUT							OUT			+125°C.							
<u>levice ty</u> be high ≥	12	æ	03 -			OUT					OUT		OUT					OUT				eept T <sub>c</sub> = +							
TABLE III. Group A inspection for device typ. Terminal conditions (pins not designated may be high $\ge$	10	7	GND	GND	=	=	=	=	=	-	-	-	-	=	-	=	=	=	=			Same tests and terminal conditions, and limits as for subgroup 9, except $T_{\rm C}$ = +125°C.							
A inspec designat	ი	9	۰g		OUT					OUT				OUT			OUT					for subgro							
<u>Group</u>	∞	S	ð	OUT					OUT						OUT	OUT						limits as				-55°C.			
TABLE III. onditions (p	9	4	PR1	2.7 V	2.7 V				Z	Z				2.7 V	=	=	=					tions, and				kcept T <sub>c</sub> =			
T/ inal con	4	ю	۱۱		2.7 V				GND	GND				2.7 V	=	=	=					nal condi				up 10, ev			
Term	e	7	K1		2.7 V				2.7 V	2.7 V				2.7 V	=	=	=					and termi				or subgro			unu
	5	~	CLK1		Z					Z				z	-	=	=					ame tests				limits as 1	are NC.		5 V maxir
	Cases <u>1</u> / 2, X	Cases A,B,C,D		80	81	82	83	84	85	86	87	88	89	06	91	92	93	94	95	66-96	100-101	102-103 Sa	104-107		108-111	Same tests, terminal conditions, and limits as for subgroup 10, except $T_c = -55^{\circ}C$ .	ferenced	2/	2.5 V minumum/5.5 V maximum
			I	F			L	8	-			e	2													inal conc	s not ref		- 2.5 V m
	MIL-STD-	883 method		Fig. 11	=	-	-	3003	Fig. 11	=	-	3000	Fig. 12	=	-	-	=	=	-	Fig. 11	3000 Fig. 1	3003	- :00: 300:	Fig. 1	3003 Fia. 12	sts, termi	d 2 pins	-	Ì
		Symbol	_	f <sub>MAX</sub>	<u>8</u> /	_		PLH1		PHL1	_	PLH2	_	_	_	PHL2	_	_		MAX 10/	PLH1	PHL1	PLH2	-	PHL2	Same te:	se X an		<u> </u>
		Subgroup		6	Tc = 25°C							-									<u>.</u>					11	1/ Ca	الم ا	I
	I	.,		1				t		t		t				t				+	t	t	t		t		I		

2.5 V minumum/5.5 V maximum

> 0

- - - 2.5 V minumum/5.5 V maximum

∧ 0

3

 $\underline{4}$ / I<sub>IL</sub> limits in mA are as follows:

mbol         A         B         C         D         F         E           L1        075/250        03/300        110/250        120/360        120/360        120/360           L2        175/550        060/600        150/560        240/720        280/760           L3        200/800        060/700        290/650        120/720        320/800					VIII/IVIAX III IIIIS IUI UU		
120/360 240/720 120/720	Symbol	A	В	С	D	F	Ш
240/720 120/720	l <sub>IL1</sub>	075/250	03/300	110/250	120/360	010/360	120/360
120/720	112	175/550	060/600	150/560	240/720	240/720	280/760
	lıL3	200/800	060/700	290/650	120/720	120/720	320/800

- $\underline{5}$ / Momentary GND, then open.
- $\underline{6}$ /  $l_{os}$  limits in mA are as follows:

ш	-7.5/-50	2.25 V
D and E	-15/-130	
U	-30/-130	:
Ф	-7.5/-50	2.25 V
A	-7.5/-50	2.25 V
Test no.	46, 48	46, 48 Q1, Q2

- $\overline{Z}$  Input voltages shown are A = 2.0 volts minimum and B = 0.7 volts maximum.
- $\underline{8}$ / Tests shall be performed in sequence, attributes data only.

45

<u>9</u>/ Output voltages shall be  $H \ge 1.5$  V and L < 1.5 V.

10/ f<sub>MAX</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

_		Unit	×	>	=	-	=	-		=	-	-	=	=	=	=	-	-	-	5 "	=		: :	-	-	-	/ mA	=	-	-	=	-	=	=		Αμ (		=
		Limits	n Max	-								0.4	-	-	-	-	-	-	-	-1.5	=			-	-	-	4/	-	-	=	-	-	=	-	-	20	-	-
_			Min	2.5	-	-	-	-	-	-	-											_	-	+			4/	-	-	-	-	-	=	-	=		_	
		Measured terminal		Q1	ġ	ð	ģ	02 02	Q2	$\overline{0}^2$	Q2	02 02	Q2	02 02	Q2	ğ	Q1	ğ	a1	CLR	К Ч	5	PR1	277	42 K2	CLK	K1	١L	JZ	K2	PR2	PR1	CLK	CLK	CLR	K1	۱L	5
00	۶	14	V <sub>CC</sub>	4.5 V	=	=	=	-	=	=	=	=	=	=	=	=	=	-	-	-	-			=	=	-	5.5 V	=	-	-	-	-	=	=	=	-	-	=
10	<u>ו</u> א	13	CLK	2.0 V	2.0 V	2/	=	-		2.0 V	=	=	=	2/	=	=		2.0 V	2.0 V							-18 mA	4.5 V	=	=				0.4 V	0.4 V	4.5 V	GND	-	=
en).	81	12	K2					2.0 V	0.7 V	-	=	-	=	-	2.0 V										-18 mA				4.5 V	0.4 V	4.5 V		4.5 V	4.5 V	4.5 V			CND CND
v, or ope	<u>0</u>	11	J2					0.7 V	2.0 V	=	=	=	=	=	0.7 V									-18 m∆					0.4 V	4.5 V	4.5 V		4.5 V		4.5 V			27 V
W ≥ U./	41	10	PR2					2.0 V	=	-	0.7 V	0.7 V	2.0 V	-	=								10 0	- 10 IIIA					>		0.4 V		<		4.5 V			CINC UNC
Terminal conditions (pins not designated may be hign ≥ ∠.U V, low ≤ U.7 V, or open)	<u>5</u>	<b>б</b>	Q2	$\left[ \right]$		$\left  \right $			4 mA		4 mA (		4 m A 2		4 mA							┥		•					-						-		-	_
e nign ≥ .	7	œ	02 02					4 mA	-	4 mA		4 mA	7	4 mA	7							╡	+	+													_	
a may pe	<u>p</u>	7	GND	GND	-	=	-	-	=	-	=	= 4	=	= 4	-	-	=	=	=	=	=			=	=	-	=	=	=		=		=	=	=	=	=	=
signated	ת	9	م. 0		4 mA		4 mA									4 mA		4 mA																			_	
				-		۸A	4									4	Ar	4	Ar																			
suid) su	α	ى ك	δ	/4 mA		4 mA										/	/ 4 mA		/ 4 mA				A					/				/	/		/	_	_	
	٥	4	PR1	0.7 V	2.0 \		=										2.0 V	0.7 \	2.0 V			-	-18 mA				_	4.5 V				0.4 \	4.5 \			GND	GNE	
	4	ო	۱L	2.0 V	=	=	0.7 V									2.0 V	0.7 V	-	-			-18 mA					GND	0.4 V				4.5 V	=	=	4.5 V	GND	2.7 V	
- Ie	γ	7	ъ	0.7 V	=	=	2.0 V									0.7 V	2.0 V	=	-		-18 mA						0.4 V	GND				4.5 V	=	=	4.5 V	2.7 V	GND	
ç	Z	~	CLR	2.0 V	0.7 V	2.0 V	=	=	=	0.7 V	2.0 V	2.0 V	0.7 V	2.0 V	=	=	=	=	0.7 V	-18 mA			Î	T			4.5 V	<u>3</u> /	3/	4.5 V			3/	4.5 V	0.4 V	GND	=	-
70000 1/	uases <u>-</u> / 2, X	Cases A,B,C,D	Test no.	1	2	e	4	S	6	7	8	6	10	11	12	13	14	15			18	19	50	17	23	24	25	26	27	28	29	30	31	32	33	34	35	36
	Ġ	883 method		3006	=	=	=	=	=	=	=	3007	=	-	-	-	=	=	=	1	[				<u> </u>	<u> </u>	3009	-	-		-		=	-	=	3010	=	-
		Symbol		V <sub>OH</sub>								OL								Q							IL1				IL4		IL6	_	IL7	H1		
		Subgroup S		-	Tc = 25°C							<u> </u>																										

# TABLE III. Group A inspection for device type 05.

See footnotes at end of device type 05.

	Unit		ЧЧ	=	=	-	=	-	=	=	=	=	=	=	шA	=	=	=	=	=																					]
-	its	Max	100	-	-	-	60	60	300	300	120	600	160	800	-100	-	-	-	8.0	8.0			See 7/	-	-	-		=	=	-	-	-	-	-	-	-	-	-	-	-	=
	Limits	Min													-15	=	=	=																							
	Measured terminal		K2	J2	۱ر	<u>қ</u>	PR1	PR2	PR2	PR1	CLR	CLR	CLK	CLK	ğı	02 02	02	ð	V <sub>cc</sub>	Vcc			AII	outputs	-	-		=	=	=	-	=	=	=	=	=	=	=		=	=
20	14	V <sub>cc</sub>	5.5 V	-	=	=	-	=	-	=	-	=	=	-	-	-	-	=	=	=			4.5 V	=		-		=	-	-	=	-	-	=	=	-	=	=	=	-	=
19	13	CLK	GND	=	=	=	=	=	=	=	=	=	2.7 V	5.5 V					GND	GND			A	В	A	A	е,	4 4	< @	A	A	в	A	A	в	A	A	ш	A	A	α
18	12	K2	5.5 V	GND				GND	GND		GND	=	-	-					5.5 V	5.5 V			В	=	=	-		=	=	-	=	-	-	-	-	-	-	-		-	=
4     6     8     9     10     12     13     14     16     7	11	J2	GND	5.5 V			l	GND	GND		GND	=	=	=					5.5 V	5.5 V			A	=		в		=	=	-	=	-	-	=	=	A	=	=		ш	=
14	10	PR2	GND	GND				2.7 V	5.5 V		GND	=	-	=		4.5 V	GND		5.5 V	GND			A	-	=	в		=	=	-	=	-	-	-	-	A	-	-	=	-	-
13	6	Q2															GND						L		-	т		=	-	-	=	=	=	=	=	_	_	т		-	=
12	ø	021 0														GND					tted.	ed.	н	=	=	_		=	-	-	=	=	-	=	=	I	I	_	=	-	=
10	7	GND	GND	=	=	=	=	=	=	=	=	=	=	=	=	-	=	=	=	=	ts are om	are omitt	GND	=	=	-		=	=	-	=	=	-	=	=	-	-	-	=	-	=
თ	9	۱ð													GND		l				nd V <sub>IC</sub> tes	V <sub>IC</sub> tests	н		=	-	:	=	=	-	=	т	т	_	_	т	_	-		-	=
8	5	ð																GND			+125°C ar	= -55°C and V <sub>IC</sub> tests are omitted.	L	=	=	-	I:	=	=	-	=	_	_	т	т	_	т	-	-	-	=
9	4	PR1			GND	GND	2.7 V			5.5 V	GND	=	-	=	4.5 V			GND	5.5 V	GND	sept T <sub>c</sub> = -	cept T <sub>c</sub> = .	A	=	=	-		=	=	-	=	=	-	в	в	A	ш	-	-	-	=
4	ς	۲					GND	$\vdash$		GND		=	-	=					5.5 V		oup 1, exc	oup 1, exc	A	=	=	-		α	ב ב	-	=	-	-	-	-	-	-	-	=	-	=
ю	7	¥					GND			GND	=	=	=	=						5.5 V	for subgro	for subgro	В	-	=	=		=	=	-	A	=	-	=	=	в	=	=	=	-	=
2	-	CLR	GND	=	=	=	=	=	=	=	2.7 V	5.5 V	GND	=	-	-	4.5 V	4.5 V	-		d limits as	d limits as	В	=	=	A		=	=	-	=	=	=	=	=	в	A	=	=	-	=
Cases 1/	Z, X Cases A.B.C.D	Test no.	38	39	40	41	42	43	44					49	50	51		53			Same tests, terminal conditions, and limits as for subgroup 1, except $T_c$ = +125°C and V <sub>ic</sub> tests are omitted.	ditions, and	Truth 3014 56 B B B A A	57	58	59	60	61 67	63	64	65	99	67	68	69	70	71	72	73	74	75
	MIL-STD- 883 ( method A		3010	=	=	-	=	=	=	=	=	=	=	=	3011	=	-	=	3005		rminal con	rminal con	D14	-	=	-				-	=	-	-	=	=	-	-	-	-	-	
							5	2	9	2	<u>6</u>	10	11	12							e tests, te	e tests, te	lth 3	le	its																
	p Symbol		I <sub>H2</sub>				IH5		9HI		6HI	IH10	H11	IH12	so				8		Sam				tests																
	Subgroup		F	Tc = 25°C																	2	З	7 <u>5</u> /, <u>6</u> /	Tc = 25%																	

TABLE III. Group A inspection for device type 05 - Continued.

See footnotes at end of device type 05.

# MIL-M-38510/301F

	Unit																					MH7	=	=	-	su	-	-		:	=	-	-	=	-	=	=	=	=	=	=
	Limits	Мах	See 7/	=	=	=	=	=	=	=	=	=	=	-	= :											21	=	=	= (	87	=	=		22	-	-	=	30	=	=	=
		Min																				75	2 =	-	=	5	=	-			-	=	-	=	-	=	-	=	=	=	=
	Measured terminal		AII	outputs	=			=	-	-	=	=	-	=	= :	= :		: :	: :	: :		6	β'δ	-20	Q2	CLR to Q1	CLR to 02	PR2 to Q2	PR1 to Q1	PR1 to 01	PR2 to 02	CLR to Q2	CLR to Q1	CLK to Q1	CLK to Q1	CLK to 02	CLK to Q2	CLK to Q2	CLK to 02	CLK to Q1	CLK to Q1
20	14	V <sub>cc</sub>	4.5 V	-	=		-		=	=	=	=	=	-								501		-	-	=	-	"		:	-	=		=	-	=	-	=	-	-	=
19	13	CLK	A	A	В	A	A	В	A	=	=	В	В	A	В	ш·	٩ı	ш	ъ.	4 ۵	۵	Z	-	-	=	-	=	=		:	=	=		=	-	=	=	=	=	=	=
18	12	K2	В	A	=	=	=	-	=	В	=	-	A	-	-	œ :		- •	4 -					2.7 V	2.7 V		GND	2.7 V			2.7 V	GND				2.7 V	2.7 V	2.7 V	2.7 V		
16	11	J2	в	-	=	=	=	=	A	В	=	-	A	-	-	œ.		- •	A -					2.7 V	2.7 V		2.7 V	GND			GND	2.7 V				2.7 V	2.7 V	2.7 V	2.7 V		
14	10	PR2	A	=	=	=	в	-	=	A	=	=	=	-	-									2.7 V	2.7 V		2.7 V	N			Z	2.7 V				2.7 V	2.7 V	2.7 V	2.7 V		
13	6	Q2	г	=	_	_	т	-	-		-	-	-	-	I					-	-				OUT			OUT				OUT					OUT	OUT			
12	8	°2	L		т	т		Γ	т	=	=	-	=	-	:						E			OUT			OUT				OUT					OUT			OUT		
4         6         8         9         10         12         13         14         16         7	7	GND	GND	=	=	=	=	=	=	=	=	=	=	-	= :							GND	-	=	=	=	=	=			-	=		=	-	-	-	=	=	=	=
6	9	۰ø	L	=	=	=	=	=	т	=	=	-	=	-	:						E		OUT			OUT			ŀ						OUT					OUT	
8	5	Q1	т	=	-	=	-	-	-	_	-	-	-	-	I					-	_	U IT	- 20						OUT				OUT	OUT							ЦС
9	4	PR1	В	=	=	=	=	=	=	A	=	-	=	-								7 \	2.7 V			2.7 V			z	Z			2.7 V	2.7 V	2.7 V					2.7 V	7 \
4	3	۲	В	=	=	=	=	=	A	В	=	-	A	-	=	œ :		= •	A :			7 1	2.7 V			2.7 V			GND	GND			2.7 V	2.7 V	2.7 V					2.7 V	77
3	2	ž	В	=	=	=	-		A	В	=	=	A	-	=	е •		- •	A :		Con	>	2.7 V			GND			2.7 V	2.7.V			GND	2.7 V	2.7 V					2.7 V	7 \
2	-	CLR	A	=	=	=	=	=	В	В	A	-	=	-	-						L P P			-	=	z	z	2.7 V			=			2.7 V	-	-	=	=	=	=	=
Cases <u>1</u> / 2, X	Cases A,B,C,D	Test no.	76	17	78	79	80	81	82	83	84	85	86	87	88	89	06	91 20	92	93	40E 0	<u>਼ = 125°C ar</u> 95	96	97	98	66	100		102	103	104	105		107	108	109	110	111	112	113	114
	883 method	1	3014	-	-	-	-	=	-	-	=	=	-	=								Kepeat subgroup / at Ic = 125°C and Ic = -55°C       f     Fin     o	) j) = -	=	-	3003	Fig. 9	=			=	-	-	3003	Fig. 10	=	=	=	=	=	-
	Symbol		Truth	table	tests																100000	Kepeat su	7/			PLH1			1	PHL1				PLH2				PHL2			
	Subgroup S		7 <u>5</u> /, <u>6</u> /																							<u> </u>								<u> </u>				<u> </u>			

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See footnotes at end of device type 05.

		Unit		MHz	su	=	=	=	
		its	Мах		32	40	32	42	
		Limits	Min	25	2	-	=		
		Measured terminal							
	20	14	V <sub>cc</sub>						
	19	13	CLK						
oen).	18	12	K2						
d. V, or op	16	11	J2						
Continue low ≤ 0.7	14	10	PR2						
<u>⊳e 05</u> - ( ≥ 2.0 V,	13	6	Q2						
device ty be high	12	8	02 02		-125°C.				
ction for ited may	10	7	GND		ept T <sub>c</sub> = +				
A inspe t designa	6	9	μğ		oup 9, exc				
I. <u>Group</u> (pins not	8	5	Q1		for subgro	1			= -55°C.
Terminal conditions (pins not designated may be high $\geq 2.0$ V, low $\leq 0.7$ V, or open).	9	4	PR1		ditions as				except T <sub>c</sub>
T minal cc	4	6	۱ſ		minal con				group 10,
Tei	ю	2	K1		ts and ter				s for subç
	2	1	CLR		Same tests and terminal conditions as for subgroup 9, except $T_{\rm C}$ = +125°C.				nd limits a
	Cases <u>1</u> / 2, X	Cases A,B,C,D	Test no.	115-118	119-122	123-126	127-130	131-134	onditions, ai
	MIL-STD-	883 method		Fig. 9	3003 Fig. 9	3003 Fig. 9	3003 Fig. 10	3003 Fig. 10	Same tests, terminal conditions, and limits as for subgroup 10, except $T_c = -55$ °C.
		Symbol		f <sub>MAX</sub> /	PLH1	PHL1	PLH2	PHL2	Same tesi
		Subgroup Symbol		10					11
	I			∞	t	t	t	t	

 $\underline{1}$  Case X and 2 pins not referenced are NC.

- --- 2.5 V minumum/5.5 V maximum 5
  - > 0
- > 0 3
- $\underline{4}$ / I<sub>IL</sub> limits in mA are as follows:

Min/Max limits for CKT

	A	В	С	D	Е
	075/250	030/300	110/250	120/360	120/360
			Min/Max limits for CKT	for CKT	
IIL4	A	8	c	Q	ш
	200/800	060/700	290/650	120/720	320/800
			Min/Max limits for CKT	for CKT	
l <sub>IL6</sub>	A	8	c	Q	Ш
	300/-1.000	300/-1.000120/-1.000	300/-1.120240/-1.440	240/-1.440	560/-1.520

1 

1

			Min/Max limits for CKT	for CKT	
lı L7	A	Я	С	D	ш
	450/-1.300	120/-1.000	580/-1.300	120/-1.500	640/-1.600

 $\overline{5}/$  Input voltages shown are A = 2.0 volts minimum and B = 0.7 volt maximum.  $\overline{6}/$  Tests shall be performed in sequence, attributes data only.  $\overline{2}/$  Output voltages shall be H  $\ge$  1.5 V and L < 1.5 V.  $\overline{8}/$  f<sub>MAX</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

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		4 - I	Ĭ		>	-	-	=	=	-	=	-	=	-	=	-	=		=		-	=	-				-	=		₩ ₩	=	-	-	-					-	hА		-
		4	2	Max									0.4	-	=	-	=	-			-1.5	-	-				-	=	-	- 2/	-		-	-					-	20		=
		- incite	5	Min	2.5	-	-	=	=	-	=	-																		- 2/	-		-	-								Π
		Meconicod	terminal		'a	۵1	ā1	Q1	Q2	02 02	Q2	- Q2	Q2	ā2	Q2	- Q2	Q1	'n	a1	°a'	CLK1	K1	11	PR1	PR2	Zn CX	CLK2	CLR2	CLR1	ξĻ	J2	K2	CLK2	CLK2	CLK1	CLK1	PR1	CLK1	PR2	K2	J2	<u>- 5</u>
	20 7	T	5 2	V <sub>cc</sub>	4.5 V	-		-	-	-	=	-	-		=	-	-		-		-	-	-				-	=	-	5.5 V	-		-	-								=
	19	4 4	<u>ი</u> ღ	CLR1	0.7 V	2.0 V	-	-									0.7 V	2.0 V											-18 mA	4.5 V 4/				-	4/	4.5 V	4.5 V	0.4 V			4	4.5 V
). <u>1</u> /	18	10	<u>t</u> ∞	CLR2					2.0 V	0.7 V	2.0 V	-	-	-	0.7 V	2.0 V												-18 mA			4/	4.5 V	4.5 V	4/				~ ~ ~	0.4 V 4.5 V	4.5 V	GND	
or open	17	α	<u>0</u> 9	CLK2					2.0 V	2.0 V	3/	-	-	-	2.0 V	2.0 V											-18 mA				4.5 V	4.5 V	0.4 V	0.4 V				1 5 1	4.5 V	GND	GND	
d 10. ≤ 0.7 V,	4 5 7 8 9 10 12 13 14 15 17 18 5 7 7 8 7 7 7 7	0	12	Z Z					2.0 V	2.0 V	0.7 V	2.0 V	2.0 V	0.7 V	2.0 V	2.0 V										-18 mA	t				4.5 V	0.4 V	4.5 V	4.5 V				1 6 //	4.5 V	2.7 V	4.5 V	
Group A inspection for device type 03 and 10 not designated may be high $\ge 2.0 \text{ V}$ , low $\le 0.7$	14	7	5	J2					2.0 V			0.7 V	0.7 V		2.0 V									_	4 C 1	-18 mA					-		4.5 V					1 2 1	_	+	2.7 V	
<u>vice typ</u>  h ≥ 2.0	13	۲ م	2	PR2					0.7 V			-	-	=		0.7 V									-18 mA	`					4.5 V	4/	_			+	-				4.5 V	
n for de y be hig	12	<u></u>	11	32					4 mA 0	~	4 mA		4 mA		4 mA	0									7						4			4		_	_	_	4 C		4	+
spectio ited ma	10	2 0	13	DNS	GND	-	-	-				-	= 4	-	" 4	-	-				-	-	-				-	=	-		-		-	=	= :					-		-
<u>oup A in</u> designa	0 7	5 1	10	02 02						4 mA		4 mA		4 mA		4 mA																		_		_	-	+				+
III. <u>Gr</u>	8	0	14	°1 10	4 mA		4 mA			<u>}</u>		·-		4		4		4 mA		4 mA														_		-	_	╉				+
TABLE III. itions (pins	7	19	15	<u>9</u>	2	t mA		t mA									mA	4	mA	4				_		T								_		_	_	+				+
ial cond	5	ۍ <b>د</b>	5 4	PR1	2.0 V	0.7 V4	2.0 V	2.0 V4									2.0 V 4	. 7 V	2.0 V 4	×0.				-18 mA			l			4/ 4.5 V				_	4.5 V	4/	4<	4.5 V			2	GND
Termir	4	0 0	0 4	11	2.0 V 2	-		2.0 V 2									2.0 V 2		0.7 V 2				-18 mA	-		T				4.5 V 0.4 V 4	-				4.5 V 4		+	+			_	4.5 V 0
	e de	20	ء 16	K1	2.0 V 2	=	=	0.7 V 2									2.0 V 2	=	-	0.7 \ 2		-18 mA	-						_	0.4 V 4 4.5 V 0	┢			_	4.5 V 4	-	-	-			-	2.7 V 4
	2 0	v •		CLK1	2.0 V 2	2.0 V	3/	<u>3/</u> 0									2.0 V 2	×0.	3/		-18 mA	7							_	4.5 V 0 4.5 V 4	┢			_	0.4 V 4	-	+	+			-	GND 2
	Cases 1/ *	*	E F		1	2	33	4	5	9	7	8	<b>б</b>	10	11	12	13 2		15	16		18	19	20	2	27.52	24	25		27 4 28 4		30	31						38	39		
				Ľ	9										Ì	<u> </u>	Ì		`	`	Ì	Ì	Ì									.,										
	MII -STD-		method		н 3006	•	-	-	-	-	-	-	٦ 3007		-	-	-	•	-	-	0									3009	-	-								1 3010		=
					V <sub>OH</sub>	5°C							OL								0									111			IL3				IL4			Ħ		_
		104.0	dnoifianc		-	Tc = 25°C							>								>									_			_				_			_		

See footnotes at end of device types 03 and 10.

## MIL-M-38510/301F

			Unit			μA	=				-	-	-	-		-	-	-	-	-	-	тA	-	=	-		=																		
			ts		Max	100	-	-	-	60	=		-	300	-	-	-	80	80	400	400	-100	-	-		8.0	8.0			See <u>8</u> /	-	-	-	-	-		=	-	-	-	-	-	=	=	-
			Limits		Min																	-15	-	-	-																				
			Measured	terminal		K1	J1	JZ	K2	CLR2	PR2	CLR1	PR1	PR1	CLR1	PR2	CLR2	CLK2	CLK1	CLK1	CLK2	Q1	م م	02 0	_ Q2	Vcc	Vcc			AII	outputs	-	-	-	-	-	-	-	-			-	-	-	-
	20	7	16 N		V <sub>cc</sub>	5.5 V	-	-	-	-	-		-		-	-	-	-	-	-	-	-	-	-	-	-	=			4.5 V	-	-	-	-	-	-	-	-	-	-	-	-	=	-	-
	19	4	15	3	CLR1	4.5 V						2.7 V	4	4/	5.5 V				GND	GND		4.5 V	GND			5.5 V	GND			В	-	-	A	-		В	A	-	-	-	-	-	=	в	A
1/	18	10	14		CLR2 0	7		DN	4.5 V	7 V	4						5.5 V	GND	0		GND	7	-	4.5 V	GND	5.5 V 5				в	-	=	A	-		В	A	=	=	-		=	=	В	A
		8	13		CLK2 CI			GND G		" 2.	=					GND	GND 5.	_			5.5 V G			GND 4.	ڻ -	-2	ڻ ۽			В	A	В	в	A	в	-	-	A	в	-	-	A	В	-	=
.7 V, or	15 ,	15	12 ,		K2 CI					Λ	ą							GND 2.			GND 5.			GND G						в	_		A	_		В					_			_	
Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open).	1								V 5.5 V										_							-	-				-			-	-		-	-	-	-	-	-	-	-	-
≥ 2.0 V,	14	12	11	6					0 4.5 V							/ 4.5 V	GND				GND			GND	. /	-	. /			A	-	-	B	-	-	-	-	-	-	-	-	-	-	A	-
e high ≩	13	6	10	7	PR2			4.5 \	GND	4/	2.7 V					5.5 V	4/	GND			GND			GND	4.5 \	GND	5.5 V			A	-	-	m	-	-	A	-	-	-	B	A	-	=	=	-
l may b	12	14	6		Q2																			GND							-	-	I	-	-	_	-	-	=	Т	-	-	=		=
signated	10	17	8	13	GND	GND	=	-	-	-	=	н	-	-	-	-	-	-	-	=	=	-	-	-	-	-	=	mitted.	itted.	GND	-	-	-	-	-	=	-	-	-	-	-	-	=	-	=
not des	6	13	7	10	ā2																				GND			ests are o	tts are om	т	-	-		-	-	т	-	-	-	_	-	-	=	т	=
is (pins	8	18	9	14	۰'n																		GND					and V <sub>IC</sub> to	ind V <sub>IC</sub> tes	т	-	-		-	-	т	-	-	-	_	-	-	=	т	=
ondition	7	19	5	15	ð																	GND						= +125°C	= -55°C a	_	-	-	т	-	-	L	-	-	-	т	-	-	=	_	=
minal c	5	3	4	2	PR1	GND	4.5 V					4/	2.7 V	5.5 V	4/				GND	GND		GND	4.5 V			GND	5.5 V	except T <sub>c</sub>	except T <sub>c</sub>	A	-	-	в	-	-	A	=	-	-	в	A	-	=	=	=
Ter	4	2	с	4	۲ſ	4.5 V	5.5 V					GND	4.5 V	4.5 V	GND				GND	GND		GND	GND			GND	GND	ogroup 1,	ogroup 1,	A	=	-	в	-	-	=	-	-	=	=		-	=	A	-
	3	20	2	16	K1	5.5 V	4.5 V					4.5 V	GND	GND	4.5 V				GND	GND		GND	GND			GND	GND	as for sut	as for sut	В	-	-	A	-	-	В	-	-	=	=	-	-	=	=	=
	* 2	** 2	•	** 1	CLK1	GND	GND					GND	GND	GND	GND				2.7 V	5.5 V		GND	GND			GND	GND	and limits	and limits	в	A	в	в	A	в	=	-	A	в	-	-	A	В	=	=
	Cases 1/	2, X	Cases *	н Ц	Test no.	43	44	45	46	47	48	49	50	51	52	53	54	55	56	57	58	59	60	61	62	63	64	Same tests, terminal conditions, and limits as for subgroup 1, except T <sub>c</sub> = +125°C and V <sub>Ic</sub> tests are omitted.	Same tests, terminal conditions, and limits as for subgroup 1, except $T_c$ = -55°C and $V_{1c}$ tests are omitted	65	66	67	68	69	70	71	72	73	74	75	76	77	78	79	80
		MIL-STD-	883	nethod	<u>I</u>	3010	-	=	=	=	=	=	=	=	=	=	-	=	-	=	=	3011	-	=	-	3005	3005	, terminal (	, terminal u	3014	-	=	-	-	-	=	-	-	-	=	-	-	=	-	-
		Σ	Symbol	-		I <sub>H2</sub>				HI5				9HI				THI		8HI		so				8		ame tests	ame tests	Truth	table	tests													
			Subgroup S			٢	Tc = 25°C			_				_												_		2 S	З З	7 <u>6</u> /, <u>7</u> / 7															

TABLE III. Group A inspection for device type 03 and 10.

See footnotes at end of device types 03 and 10.

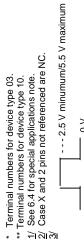
## MIL-M-38510/301F

			Unit																MHz		=	=	su	=	-	=	-	-	-	=	-	-	-		-			MHz	su	-	-		-	
			Limits		Max	See <u>8</u> /	-	-						-	=	-	-						21	-	-	=	28	-	=	-	22	-	-	- 6	00 -				32	40	0.0	32	42	
			μ		Min														25		-	-	5	=		-	-	-	=	-		-	-		-			25	5	-			=	
			Measured	terminal		AII	outputs							=	-	-	=		g	° 10	_ 02	Q2	CLR1 to 01	PR1 to Q1	CLR2 to 02	PR2 to Q2	CLR2 to Q2	PR2 to 02	CLR1 to Q1	PR1 to 01	CLK1 to 01	CLK1 to Q1	CLK2 to G2	CLK2 to Q2		CLK2 to Q2	CLK1 to Q1 CLK1 to Q1							
	20	7	16	5	V <sub>cc</sub>	4.5 V	-							-	-	-	-		5.0 V		=	-	-	-	-	-	-	-	-	-	-	-	-											
	19	4	15	3	CLR1	A	-	-			= (	20 1	я <	≮ =	=	-	-		2.7 \	2.7 V			z	2.7 V					Z	2.7 V	2.7 V	2.7 V					2.7 V 2.7 V							
1	18	10	14	8	CLR2	A	=	-			= (	ы	л <	₹ =	-	-	=	-			2.7 V	2.7 V			z	2.7 V	Z	2.7 V					2.7 V	2.7 V	2.7 V									
r open).	17	8			CLK2	A	В	-	= •	A	в.	۲	20 0	2 ₫	с <b>п</b>	A	в	-			z	z			z			z						z				_						
<u>na_10</u> . ≤ 0.7 V, or open).	15	15	12	12		В	-	A						-	=	=	=	-			2.7 V	2.7 V			GND	7 V	GND	2.7 V					2.7 V	2.7 V	∧ / /				ပ္ပ					
<u>u3 and</u> , low ≤ (	14	12		6		A		В			_	A :					_	-			2.7 V 2.	2.7 V 2		-	2.7 V G	_		GND 2						2.7 V 2				_	Same tests and terminal conditions as for subgroup 9, except $T_{\rm C}$ = +125°C					
וו שבעבינוסו זסן אדער איז	-			_										+				-	-					$\vdash$								┢		$\vdash$	-				9, except					
or devi	13		10		PR2	A	-	В	A.		- (	л ·	¥ =	-	-	-	-	-			2.7 V	Γ 2.7 V			2.7 V		F 2.7 V							F 2.7 V	_	i			subgroup					
d may h	12	_			02		Т	-				I ·		-	Т	Т		-	_			OUT				ΟŪ	OUT								3			_	ons as for					
I ABLE III. Group A inspection for device type 0.3 and 10 itions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$	10	17		13		GND	-	-						-	-	-	-		GND GND		-	-	•	=	-	-	-	=	-	-	-	-	-		-			_	al conditic					
i not de	6	13	7	10	02 02	н		-			τ·			-	_		т	-	_		OUT				OUT			OUT					OUT		OUT				ind termin					
us (pins	ø	18	9	14	'n	н		-		-	I.			-	_		т	-	ł	TUO			OUT							OUT	OUT						OUT		ne tests a					
onditio	7	19	5	15	ð	Γ	т	-				Γ.		-	т	т			OUT					OUT					OUT			OUT					OUT		Sai				,	ŝ
minal c	5	3	4	2	PR1	A	-	В	A		= (	ъ	× -	-	=	=	-	-	2.7 <				2.7 V	Z					2.7 V	Z	2.7 V	2.7 V					2.7 V 2.7 V						ļ	of $T_c = -56$
Tei	4	5	3	4	5	A	-	в			- •	A :		=	-	-	-		2.7 <	2.7 V			2.7 V	GND					2.7 V	GND	2.7 V	2.7 V					2.7 V 2.7 V						1	10. excet
	3	20	2	16	ž	В	=	A						-	=	=	-	c = -55°C.	2.7 \	2.7 V			GND	2.7 V					GND	2.7 V	2.7 V	2.7 V					2.7 V 2.7 V							subaroup
	* 2	** 2	* 1	** 1	CLK1	A	В			A	B	٩	8 0	۵ ۵	с <b>п</b>	A	В	°C and T <sub>c</sub>	Z	Z			z	IN					Z	Z	Z	N					zz						,	ons as for
	Cases 1/	2, X	Cases	г Ц	Test no.	81	82	83	84	85	86	8/	88	88	91	92	93	at $T_{\rm C} = +125$	f <sub>MAX</sub> Fig. 9 94 IN 2.7 V	95	96	26	98 <u>10</u> /	66	100	101	102 10/	103	104	105	106	107	108	109	111		112 113	114-117	118-121	122-125		126-129	130-133	Same tests and terminal conditions as for subaroup 10. except $T_c = -55^{\circ}C$
		MIL-STD-	883	method	_	3014	-	-						-	-	-	=	1 dno.pdr.	Fig. 9		-	-	3003	Fig. 9	-	-	-		-	-	3003	Fig. 10	-					Fig. 9	3003 Eia 0	3003	Fig. 9	3003 Fig. 10	3003 Fig. 10	ts and terr.
		-	Symbol				table	tests										Repeat st	f <sub>MAX</sub>	/6			PLH1				PHL1				PLH2			T	PHL2			f <sub>MAX</sub>	PLH1	PHL1	-	PLH2	PHL2	Same tes
			Subgroup			7 6/, 7/	$Tc = 25^{\circ}C$												ი								t.								_			10	t .			t		1

TABLE III. Group A inspection for device type 03 and 10.

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See footnotes at end of device types 03 and 10.







 $\overline{5}$ / I<sub>IL</sub> limits in mA are as follows:

Min/Max limits for CKT

	<b>I</b> L1	A	8	ပ	D	ш
		075/250	030/300	150/560	120/360	120/360
I						
			Min	Min/Max limits for CKT	КТ	
	<b>I</b> L3	A	В	ပ	۵	ш
		150/500	060/600	250/560	240/720	280/760
			Min	Min/Max limits for CKT	KT	
	IL4	A	В	ပ	۵	ш

 $\underline{6}$  Input voltages shown are A = 2.0 volts minimum and B = 0.7 volts maximum.

-.320/-.800

-.120/-.720

-.290/-.650

-.060/-.700

-.200/-.800

 $\overline{\mathcal{I}}$  Tests shall be performed in sequence, attributes data only.

<u>8</u>/ Output voltages shall be  $H \ge 1.5$  V and L < 1.5 V.

g/ f<sub>hax</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

<u>10</u>/ These tests may be performed as shown in table III or alternately as follows:

1									
	V <sub>cc</sub>	5.0 V	=	=	=	=	=	=	=
	CLR1	Z	2/					N	2/
	CLR2			Z	2/	N	2/		
	CLK2 CLR2			2.7 V	2.7 V	2.7 V	2.7 V		
	K2			2.7 V	2.7 V				
	٦C			2.7 V	2.7 V	2.7 V	2.7 V		
	PR2			2/	IN	2/	NI		
	Q2				OUT	OUT			
	GND	GND		=			=		=
	_ Q2			OUT			OUT		
	ūم	OUT							OUT
	۵۱		OUT					OUT	
	PR1	77	NI					2/	NI
	۱ſ	2.7 V						2.7 V	2.7 V
	K1	2.7 V	2.7 V					2.7 V	2.7 V
	CLK1	2.7 V	2.7 V					2.7 V	2.7 V
	Test no.	98A	99A	100A	101A	102A	103A	104A	105A

		Unit		>=	-	-	-	=	-	-	-	-	=	-		-	-	-	=	-	-	-	-	-			=	V.w.	¥II	-	-	-	-	-	-	μA								-	-	-			-	-	]
			Max						0.4	-	=					-	-			-	-1.5	-	-				-	10	ò.		-	-	-	-	-	20						= 7		100	-	-				-	-
		Limits	Min	2.5	-	=	-	=																				10	ò		-	-	-	-	-									-					T		-
		Measured terminal		60	22	04	Q5	Q6	QG	Q5	Q4	Q3	Q2	Q1	Q1	Q2	Q3	Q4	Q5	Q6	CLR	D1	D2	D3	CLK	D4	20	20	20	22	5 2	36	10	CLR	CLK	CLR	D1	70	U3	CLK	D4	D5	D6	D6	D5	D4	CLK	D3	70	- R -	
																				-		_	_								+		-		-	-										-					_
	20	16	V <sub>cc</sub>	4.5	-	-		" YU		-	=	=			-	-	-	=			-	-	=				=	7 2	0.0	-	=	-	=	-	-	=					-			-	-	-			-	-	_
	19	15	90 06				_	_	4 mA											4 mA							<	1.														_	_	_					+	_	_
pen).	18	14	D6				_	2.0 V	0.7V																_		_	-10 III A	-														2.7 V		_				_	+	_
7 V, or c	17	13	D5				2.0 V			0.7 V																V 0 F	111 01-			0.4 V												2.7 V	_		5.5 V				+		_
ow ≤ 0.7	15	12	Q5				4 mA			4 mA									4 mA																																
2.0 V, lo	14	11	D4			201	2.1				0.7 V															-18 mA				1110	0.4 <										2.7 V				1	5.5 V					
Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open).	13	10	Q4			- 4 mA					4 mA							4 mA																											1						
may be	12	6	CLK	-2/	-	-		=	-	-	-	-													-18 mA										0.4 V					2.7 V			-	-			5.5 V		T		-
gnated	10	œ	GND	GND GND	-	-		-	-	-	=		н		-	-	-		н	-	-	-	-				-	=			-	-	-	-	-	=					-			=	-	-			-	-	
not desi	თ	7	Q3		- 4 mA							4 mA					4 mA																											-					T		-
s (pins r	ω	9	D3		201	+						0.7 V												-18 mA							111	0.4 <						Ì	Z. / V					-				5.5 V	+	T	-
nditions	7	ى ک	Q2	V 1	_								4 mA			4 mA										T					T											-		-				T	T	-	-
ninal co	5	4	D2										0.7 V										-18 mA									0.4 V						Z. / V				_	-	_					> c.c	-	-
Tern	4	e	Б	_										0.7 V								-18 mA	ì										0.4 V				2.7 V					_		_					557	,	-
	e			4 mA 2	+								_	4 mA 0	i mA							-				┥	+		+		╈						. 4					┥	+	-	-			+	4	+	_
·	5			2.0 V 	=	=	-	-	=	-	=	=	=		0.7 V 4	-	=	=		-	-18 mA				+	+	+				+			0.4 V		2.7 V	+					+	╉	+			+	+	╉	5.5 V	~ ~ ~ ~
	Cases <u>1</u> / 2, X		Test no. (		N 67	4	5	9	7	8	6	10	11		13 0	14	15	16	17	18		20	21	22	23	24	07	07	17	8 0	50	31	32				36	3/	20	39	40	+1	42	43	44	45	46	47	48		
																,	,					. 4	. 1	- 1															1		7		4	7	7	7	7				
	MIL-STD-	bol 883 method		+ 3006	-	-	•	-	3007		-	-	-	-	-	-	-	-	-	-								0006			-	-	-			3010					-		-		-	-			-	-	_
		up Symbol		HON CO-	ړ				lo												<u></u> ₽								5					112		H								IH2							_
		Subgroup			1 C = 72				>												>								_					_		_								_							

TABLE III. Group A inspection for device type 06.

See footnotes at end of device types 06.

		Unit		μA	-	-	-	-																			MHz			T			ns	_	-	_						_	-	-		_	_	_		
		2	×										/7														Σ																					+	_	_
		Limits	n Max			-	-	-	=	26			See <u>7</u> /	=	-	-		=	-	-	-	=		-	-		_	_	_	_		_	42	-	-	-		-	37	-	-	-	-	-	40	=	-	-	-	
			Min	-15	-	-	-	-	-																		25	-	-		-		5	-	-	-				=	-	-	-	-	-	-	-			
		Measured terminal		م 1	Q2	Q3	Q4	Q5	Q6	V <sub>cc</sub>			AII	outputs	=	-		=	-	-	-	-	-	-			a b	Q2	Q3	Q4	Q5	Q6	CLR to Q6	CLR to Q5	CLR to Q4	CLR to Q3	CLR to Q2	CLR to Q1	CLK to Q1	CLK to Q2	CLK to Q3	CLK to Q4	CLK to Q5	CLK to Q6	CLK to Q6	CLK to QE	CLK to Q4	CLK to Q3	CLK to UZ	CLK to U
	20	16	V <sub>cc</sub>	5.5 V	-	-	-	-	-	-			4.5 V	-	-	-	-	=	-	-	-	=	=	-	-		5.0 V	-	-		-	-	-	-	-	-				-	-	-	-	=	-	=	-			
	19	15	90 00						GND				_	=	-	-	-	н	-			_	н	т	_							OUT	OUT											OUT	OUT					
n).	18	14	D6						4.5 V	5.5 V			A	-	-	-	-	=	в		-	A	=	-	-							z	2.7 V											N	Z				Ī	
, or ope	17	13	D5					4.5 V		5.5 V			A	-	-	-			В	-	-	A		-	-						z			2.7 V									N			N				
2.0 V, low ≤ 0.7 V, or open)	15	12	Q5					GND					L	=	-	-	-	н	=	-		_	н	т	_						OUT			OUT									OUT		H	OUT		╡	+	
V, Iow	14	11	D4				4.5 V	-		5.5 V			A	-	-	-	-	=	В		-	A	=	-	-					z	-			_	2.7 V						_	z	_				Z	_	-	
h ≥ 2.0										5.																					_								_								Τ	_	_	
/ be hig	13	10	< Q4				GND						_	=	-	-	-	Т	-	-			Т	I	_			_		DO					OUT							OUT					.no	_	_	
ed may	12	6	O CLK	0 4/	-	-	-	-	-	-				В	A	A	В	A	A	В	A	В	A	В	В		⊒ ○	-	-		-	-	-	-	-	-				-	-	-	-	-	-	=	-			
esignat	10	ω		GND	-	-	-	-	-	-	omitted.	nitted.	GND	-	-	-	-	-	-	-	-	=	-	-	-		GND	-	-		-	-	-	-	-	-				-	-	-	-	-	-	=	-	- ·	-	
is not d	6	2	Q3			GND					ests are c	sts are on	_	-	-	-	-	т	=	-			т	т					OUT							OUT					OUT							OUT	_	
ons (pir	œ	9	B			4.5 V				5.5 V	and V <sub>IC</sub> t	C and V <sub>IC</sub> tests are omitted.	A		=	-	=	=	В	-	-	A	=	-	-				≥							2.7 V					Z							Z		
Terminal conditions (pins not designated may be high $\geq$	2	2	Q2		GND						= +125°C	= -55°C a		-	-	-	-	т	-	-	_	L	т	т	_			OUT									OUT			OUT								1	OUT	
erminal	2	4	D2		4.5 V					5.5 V	except T <sub>c</sub>	except T <sub>c</sub>	A	=	-	-	-	=	В		-	A	=	-	-			Z									2.7 V			Z									Z	
Te	4	0	5	4.5 V						5.5 V	group 1, e	group 1, e	A	-	-	-	-		в	-	-	A	-	-	-		Z											2.7 V	Z											z
	3	2	6 B	GND							as for sub	as for sub	L	=	-	=		н	=	-	_	_	н	т	_	= -55°C.	OUT										1.0		001											OUT
	2	-	CLR	4.5 V	=	-	-	-	-	5.5 V	and limits ;	and limits ;	В	=	-	A	-	=	-	-	-	=	=	-	в	C and T <sub>C</sub>	2.7 V	-	-		-	-	z	-	-	-			2.7 V	-	-	-	-	=	-	=	-	-		-
	Cases <u>1</u> / 2, X	Cases E, F	ö	_	52	53	54	55		57	Same tests, terminal conditions, and limits as for subgroup 1, except $T_c$ = +125°C and $V_{ m lc}$ tests are omitted.	onditions, a	58	5°C table " 59 " " " " "	60	61	62	63	64	65	66	67	68	69	70	Repeat subgroup 7 at $T_c = +125^{\circ}C$ and $T_c = -55^{\circ}C$ .		72	73	74	75	76	77	78	79	80	81			84	85	86	87	88	89	06	91	92	93	94
	MIL-STD-	883 method	<u>ſ</u>	3011	-	-	-	-	-	3005	terminal c	terminal c	014	-	-	-	-	-	=	-	-	=	-	-	-	roup 7 at	Fig. 13	-	-			-	3003	g. 13	-	-			003	Fig. 14	-	=	-	-	003	Fig. 15				
	MIL	Symbol 8		los 31						SC CC	ne tests, i	ne tests, i	uth 3	ble	sts											peat subg	f <sub>MAX</sub> Fig						PHL1 3	ſĹ,				_	PLH2 3	ιĹ					PHL2 3					-
		Subgroup Syr		-								3 San	7 <u>5</u> /, <u>6</u> / Tri	25°C ta.	te											8 Rep							đ						đ.						Ē					-
		Subg			Tc = 25°C						. 4		75/	Tc =												~		Tc = 25°C																						

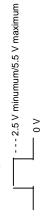
TABLE III. <u>Group A inspection for device type 06</u> - Continued.

See footnotes at end of device types 06.

## MIL-M-38510/301F

		Unit		MHz	su	-	-	
		its	Max		52	47	52	
		Limits	Min	25	5	-	-	
		Measured terminal						
	20	16	V <sub>cc</sub>					
	19	15	90					
en).	18	14	D6					
l. V, or op	17	13	D5					
TABLE III. Group A inspection for device type 06 - Continued. Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open).	15	12	Q5					
<u>e 06</u> - Ci 2.0 V, Ic	71	11	D4					
<u>vice typ</u> ∍ high ≥	13 14	10	Q4					
n for de I may b€	12	ი	CLK					
<u>nspectic</u> signatec	10	8	GND		= +125°C			
oup A i	6	2	Q3		ot T <sub>c</sub> . T <sub>c</sub>			
E III. <u>Gr</u> ns (pins	8	9	БЗ		lexcel			
TABLE	7	2	Q2		or subgrou			c = -55°C.
erminal	5	4	D2		ditions as f			, except T <sub>c</sub>
Τe	4	ę	Б		Same tests and terminal conditions as for subgroup 9, except $T_{\rm C},~T_{\rm C}$ = +125°C			bgroup 10
	ŝ	2	ð		sts and ter			s as for su
	2	۲	CLR		Same te:			, and limits
	Cases <u>1</u> / 2, X	Cases E, F	Test no.	95-100	101-106	107-112	113-118	<sup>1</sup> conditions
	MIL-STD- 2, X	883 method		Fig. 13	3003 Fig. 13	3003 Fig. 14	3003 Fig. 15	Same tests, terminal conditions, and limits as for subgroup 10, except $T_c = -55^{\circ}C$ .
		Symbol		f <sub>MAX</sub>	PHL1	PLH2	PHL2	Same te:
		Subgroup Symbol	_	10	_	_	_	11
I				8	t	t	t	

<u>1</u> Case X and 2 pins not referenced are NC. <u>2</u>



 $\underline{3}$ / I<sub>IL</sub> limits in mA are as follows:

			Mi	Min/Max limits for CK	CKT			_
[_1	A	8	C	D	Э	Ŀ	თ	-
	085/270	100/340	075/250	075/250	120/360	160/400	075/250	
			Mi	Min/Max limits for CKT	СКТ			
	V	α	ل	2	ц	ц	Ċ	_

				Mi	Min/Max limits for CKT	СКТ		
	l <sub>IL2</sub>	A	В	С	D	Ш	ш	ŋ
		115/350	150/420125/275	125/275	120/360	120/360	150/380	.150/380075/250
				for test 33			for test 33	for test 33
				160/400			160/400	120/360
				for test 34			for test 34	for test 34
4								

T

56

2.5 V minumum/5.5 V maximum 0 V

 $\overline{5}$ / Input voltages shown are A = 2.0 volts minimum and B = 0.7 volts maximum.

 $\underline{6}'$  Tests shall be performed in sequence, attributes data only.

 $\overline{2}$  Output voltages shall be H  $\ge$  1.5 V and L < 1.5 V.

8/ f<sub>MAX</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

		Unit		>	-	-	-		-	=	-	-	-	-	=			=	=	-	-	=		=	-		-	=	=	mA "		=	=	-	ЧЧ		-		]
		its	Max												0.4 V			-	-	-	-	-		-	-1.5 V		-	-	-	ю.	. =	-	-	-	20		-		
		Limits	Min	2.5	-	-	-		-	-	-	=	=	-																<u>ہ</u>	. =	-	=	=					
		Measured terminal		ο' 1	ā2	03 03	ā4	Q4	80	Q1	ā1	ā2	ā3 G3	_ Q4	Q1	Q2	04	04 04	03 03	ā2	a,	a1	02 03	04 04	CLR	50	CLK	D3	D4	D4	200	10	CLR	CLK	CLR	56	CLK	D3	5 4
	20	16 7 A	V <sub>cc</sub>	4.5 V	-	-	-					-	-	-	-					-	-	=		-				-	-	5.5 V "	_	-	-	-	-		-		_
				4.				An									A							Ā					_	5.	-	+				_	-		_
	19	15	Q4				A	4 mA						A			4 mA							4 mA							_	╞				_	-		_
pen).	18	14	04 <sup>1</sup>				4 mA							4 mA				4 mA											1		_	L				_	_		_
V, or c	17	13	Δ					2.0 V						0.7 V				2.0 V						0.7 V					-18 mA	0.4 V		+				_		11 2 0	× 1.7
ditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open).	15	12	D3					200	2.U V				0.7 V						2.0 V				1120	A. 1.0				-18 mA			0.4 V							2.7 V	
2.0 V, Ic	14	11	ā 3			4 mA							4 mA						4 mA																				
high ≥ 2	13	10	03 O3					Λ Λ	4 II 4								4 mA						1 m A	5								Ī							
nay be	12	ი	CLK					<u>-</u> -		=	-	=	-	-			2/	=	-	-	-	= :		=			-18 mA					╉	H	0.4 V		_	2.7 V		-
nated r	10	æ	GND	GND	-	-	-		-		-	-	-	-	=			-	-	-	-			-				=	-			-	=	=	= :				
ot design	ი	7	Q2						4 mA							4 mA							4 mA						_			T				_			-
(pins no	ø	9	ā2		4 mA				;			4 mA				4	+			4 mA			4								+	+							-
ditions	2	5	D2		4				۸ O			7 /								0 N			7 /				- 18 MA		_		041	, t				7 \	, ,		-
Terminal con	5		5						2	2.0 V	<i>۲</i> ۷	0								5	2.0 V	0.7 V	Ö			-18 mA	Ĩ		_		- -	0.4 V				2.7 V 2			_
Termi	4	с С	α1 Γ	4 mA						_	4 mA 0.										4 mA 2.	0.				-18					+	O				i,	-		_
				4						-	4				Ar		-				41	٩	+	-							+	╞				+	_		_
	ε	2	۶ ۵	>	_			>		4 mA					V 4 mA		_	>		_		4 mA	_		hA						_	╞	~		>	+	-		_
	<u>1</u> / 2			0.7 V	-	-	-	2.0 V "	-	-	-	-	-	-	0.7 V			2.0 V	-	-	-	-		-	-18 mA							F	0.4 V		2.7 V	_			_
	0	Cases E, F	Test no.	-	5	e	4	υ Ω	0	8	6	10	11	12	13	14	15 16	17	18	19	20	21	22	24	25	26	28	29	30	31	32	348	35	36	37	88	40	41	44
	MIL-STD-	883 method		3006	-	-	-				-	-	-	-	3007					-	-	-		-						3009	-	-	-	-	3010				
		Symbol		V <sub>он</sub>											OL										<u>∪</u>					IL1			211		Ħ				
		Subgroup		-	Fc = 25°C					-							_					_	_	-		-	_			-									1
	L	S		I	Ë.										>										>					_			-		-				1

TABLE III. Group A inspection for device type 07.

See footnotes at end of device type 07.

		Unit		hА	-	=			ШA	-	-	-			-	-	-															MHz		-	=	=	-	-	=	su	-	-	=	7
		iits	Max	100	-	-		=	-100	=	=	-			-	-	18			See <u>7</u> /	-			=	-				=	-										32	-	-	=	
		Limits	Min						-15		-		1		-																	25		-	-	-	-	=	-	5	-	-	-	
		Measured terminal	•	D4	D3	CLK	D2	2	0- CLA	. c	N C	n X I	Q4	04 02	300	9 0	V <sub>cc</sub>			AII	outputs			=	-				-	-		a 1	٩.	_ 02	Q2	Q3	03 03	- 04	04	CIR to 04	CLR to 03	CLR to 0.2		CLR to Q1
	20	16	V <sub>cc</sub>	5.5 V	-	=		=	-	-	-		1		-		-			4.5 V				=	=				=	-		5.0 V		-	=	=		-	=	-	=	-	-	
	19	15	Q4											GND						L	= 1		E	=	=	•		- 1	- I	:									OIT					
и).	18	14	04									UND	2		T					г				J =	=	т·			J	ιI								OUT		OUT				_
or opei	17	13	D4	5.5 V										4.5 V	T		5.5 V			A				-	в			×⁼	-	-								z	Z	2.7 V				_
/, low ≤ 0.7 V,	15	12	D3		5.5 V									+	> C.4		5.5 V			A				-	в			4 =	-	-						N	z				2.7 V			_
	14	11	ā 3								GND									н				J =	-	т·			J	н							OUT				OUT			_
ins not designated may be high $\ge 2.0^{\circ}$	13	10	ß														ľ			L			E I	-	-	- -		- 1	. 1	:						OUT	0				0			_
ay be hi	12	6	CLK 0			5.5 V	+							4/						В	A	200			m	A	201	B ⊲				∠ -			-	•			=			_	_	_
ated ma	10 1	8		GND				=		-	-						-			GND	-			-	-				-	-		GND -		-	-	-		-	-		=	-	-	_
t design	6	7	Q2 G	U											UND	P		re omitted.	omitted.				. т	-	-				. 1			U			OUT									_
pins no	8	9	02 02							GND					Ċ	2		V <sub>IC</sub> tests a	55°C and V <sub>IC</sub> tests are omitted	г					-	т		_		н				OUT	0							OUT		_
nditions (p	7	5	D2 0				5.5 V			U					4 5 \/	>	5 V	25°C and 1	°C and V <sub>k</sub>	A				-	в			A=	-					o N	z							2.7 V 0		_
inal con	5	4	D1				E E V	> 0							V	t 2 <	5.5 V 5.	pt $T_c = +1$ ;	pt $T_c = -55$					-	в			<	-			z	z	_								i2	2.7 V	
Termi	4	33	α1 Γ				L	ö	GND							4	.5	up 1, excel	up 1, excel	н				J =		т				т													OUT 2.	
	3	5	01 01						U							GND	2	or subgrot	or subgrot	L			т						- I		55°C.	OUT	C										0	' 
	2	-	CLR 0			_	+	~ 4	OND					4.5 V "		ڻ -	5 V 0	limits as f	limits as f	в		. <	4 =	_	-				_	В	and T <sub>c</sub> = -5	_			-	-			-	Z		_	_	_
				3	4	5	9 0		1	C	-				4 I/	2.00	cc 3005 57 5.5 V 5.5 V 5.5 V	itions, and	Same tests, terminal conditions, and limits as for subgroup 1, except $T_c = -$	- o	6			4.00	4		_		0.0		Repeat subgroup 7 at $T_c = +125^{\circ}C$ and $T_c = -55^{\circ}C$ .	1 2.7 V	N					2	~		0		~	-
	-D- Cases <u>1</u> / 2, X	d E, F	Test no.		4	4	46	4 4	49	50	51	52	Ď	53	άŭ	οŭ Ω	22	ninal condi	ninal condi	ž	59	ũ ů	υ Ω	o io	9 Q	65	õ	ω ŭ	ó c	7(	p7atT <sub>c</sub> =		7.7	73	77	75	74	17	78		3 80	81	82	i 
	MIL-STD-	ol 883 method		3010	-	-	• •	-	ĕ	-	-	-	1		•	•	3005	tests, tern	tests, tern	3014				-	-	• •			-	-	tt subgrou	Fig. 13		•	-	-	•	•	-	3003	Fig. 13	-	=	
		Ip Symbol		I <sub>H2</sub>					SO								8	Same	Same	/ Truth	°C table	tests										f <sub>MAX</sub>								PLH1				_
		Subgroup		-	Tc = 25°C				_								_	2	с	7 <u>5</u> /, <u>6</u> /	$T_{c} = 25^{\circ}$										8 <u>4</u> /, <u>5</u> /	б 	T <sub>C</sub> = 25°C							t				

TABLE III. Group A inspection for device type 07 - Continued.

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See footnotes at end of device type 07.

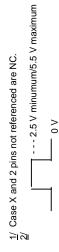
		Unit		ns		-	-	-	-	-	=		=	-	-	-	-	-		-	=			su	=	=	=	-	-		-	Π
		its	Max	45		-	- ;	35	-	-	-		-	-	-	40		-	-	-	=		-		51	55	46	46	55		55	
		Limits	Min	5		-		-	-	-	-		-	-	-	-	-	-	-	-	=		-	25	5	-	-	-	-		-	
		Measured terminal		CLR to Q1	CLR to Q2	CLR to Q3	CLR to Q4	CLK to Q4	CLK to Q3	CLK to Q2	CLK to Q1	CLK to 01	CLK to 02	CLK to 0 3	CLK to 04	CLK to 04	CLK to 0 3	CLK to 02	CLK to 0 1	CLK to Q1	CLK to Q2	CLK to Q3	CLK to Q4						_			
	20	16	V <sub>cc</sub>	5.0 V (		-		-		-	-	-	-	-	-	-	-	-	-	-												
	19	15	Q4				OUT	OUT														ł	OUT									
.(c	18	14	04 04												OUT	OUT																
or oper	17	13	D4				2.7 V	Z							z	z							Z									
≥ 2.0 V, low ≤ 0.7 V, or open)	15	12	D3			2.7 V			Z					z			z					z										
V, low :	14	11	ā 3											OUT			OUT															
jh ≥ 2.0		10	03			Т			Т	_				0			0					Ц										
y be hig	-					OUT			OUT													OUT										
ted ma	12	6	D CLK	D		-		-			-	-	-	-	-	=	-	-	=	-	=		-									
designa	10	ø		GND	- ·	-		-		- ⊢	-	-	-	-	-	-	-	-	-	-	- -					+125°C						
ns not	ი	2	02		DO					OUT			_								OUT					(cept T <sub>c</sub> =						
onditions (pins not designated may be	α	9	02		/					_			OUT					OUT								iroup 9, e)						ö
Terminal conditions (pins not designated may be high	2	5	D2	/	2.7 V					Z			Z					Z			N					Same tests and terminal conditions as for subgroup 9, except $T_{\rm C}$ = +125°C						$T_{\rm C} = -55^{\circ}$
Termina	വ	4	Б	2.7 \			_				≧								Z	≧						onditions a						10, except
·	4	e S	۰ő									OUT							OUT							erminal co						ubgroup '
	ო	7	ð	OUT							OUT									OUT						ests and t						its as for s
	5	-	CLR	Z		-	=	2.7 V	-	-	-	•	-	-	-	-	-	-	-	-	=				1			1				s, and limi
	Cases <u>1</u> / 2, X	Cases E, F	Test no.	83	84	85	86	87	88	89	06	91	92	63	94	95	96	26	86	66	100	101	102	103-110	111-114	115-118	119-122	123-126	127-130		131-134	Same tests, terminal conditions, and limits as for subgroup 10, except $T_{\rm C}$ = -55°C.
	MIL-STD-	883 method		3003	Fig. 13		=	3003	Fig. 14	-	-	3003	Fig. 15		-	3003	Fig. 14	-		3003	Fig. 15			Fig. 13	3003 Fia. 13	3003 Fin 13	3003 Fig. 14	3003 Eig 15	3003	Fig. 14	3003 Fig.15	sts, termine
		Symbol		t <sub>PHL1</sub>				PLH2								PHL2				1				f <sub>MAX</sub>	PLH1	PHL1	PLH2	PLH2	PHL2		PHL2	Same tes
		Subgroup		6	Tc = 25°C			t								ţ								8	t	t	t	ţ	-		t.	11

TABLE III. Group A inspection for device type 07 - Continued.

See footnotes at end of device type 07.

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end of device



 $\underline{3}$ / I<sub>IL</sub> limits in mA are as follows:

lı Lı	A	в	ပ	D	ш	Ŀ	ტ
	075/250	100/340075/250	075/250	075/250	120/360	160/400	075/250
			Mi	Min/Max limits for CKT	OKT		
lı.2	A	В	ပ	D	Ш	ц	Ċ
	085/270	150/420	150/420125/275	120/400	120/400	105/380	075/250
	for test 35		for test 35	for test 35		for test 35	for test 35
	135/400		160/400	120/360		160/400	120/360
	for test 36		for test 36	for test 36		for test 36	for test 36

Min/Max limits for CKT

4



- $\overline{5}$ / Input voltages shown are A = 2.0 volts minimum and B = 0.7 volts maximum.
- $\underline{6}$ / Tests shall be performed in sequence, attributes data only.

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- $\overline{2}/$  Output voltages shall be H  $\geq$  1.5 V and L < 1.5 V.
- g/ f<sub>MAX</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

		Unit		>	=	-	=	-	=	-	-	=	-	=	-	=	-	-	-	=	-	-	=	-	-					-	-	=	-	=					-	1
		iits	Max									0.4	-	-	-	=	-	-	-	-1.5	-	-	=	=	-					ři =	-	=	-	-					-	1
		Limits	Min	2.5	-	-	-	-	-		-																		11	fi =	-	-	-							
		Measured terminal	•	م. 10	۵1	م. 10	۵1 م	02 02	Q2	<u>0</u> 2	Q2	Q2	02	Q2	02 02	<u>م</u> 1	ه، 1	۵1 م1	ā1	CLR1	11	K 1	CLK1	PR1	PR2	CLK2	K 2	J2	CLK2	- 12 -	K 2	J2	CLK2	CLK2	PR2	PR1	CLK1	CLK1	CLR	CLKZ
	20	16	V <sub>cc</sub>	4.5 V	-	-	=	-	-	=				-	-	=	-	-	-	-		-	=	=				-		> ? =	-	=								
	19	15	CLR2					0.7 V	2.0 V	-	-	0.7 V	2.0 V	-	-														-18 mA		4.5 V	3/	3/	4.5 V	GND			T		0.4 V
	18	14	72					0.7 V	-	-				-	2.0 V													-18 mA	ì		4.5 V				-	+	+	+	_	4.5 V
Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open).	17	13	кі К					0.7 V 0	-	-				-	2.0 V 2											10		-7			0.4 V 4	4.5 V 0	-		-	_	+	+	-	4 V C.4
0.7 V, c	15								ą	/	-		Ģ														-							٧.	>	_	_	+	+	
', low ≤	1		2 CLK2					V GND	V GND	v <u>2</u> /	2	GND			۷ <u>ک</u> /											-18 mA					GND		_			_	_	_	_	۲.5 V
≥ 2.0 V	14	11	PR2					2.0 V	-	2.0 V	-		0.7 V	2.0 V											-18 mA						3/	4.5 V	4.5 V	3/	0.4	_	_	_		GND
oe high	13	10	02						4 mA		4 mA	4 mA		4 mA																										
d may t	12	6	0 N					4 mA		4 mA			4 mA		4 mA																							_		
signate	10	ω	GND	GND	-	-	=	-	=	-	-		-	=	-	=	-	-	-	-		-	=		-			-		-	-	=	-						-	
i not de	ი	2	'ą	-4 mA		4 mA											4 mA		4 mA																					
ns (pins	8	9	Q1		4 mA		4 mA									4 mA		4 mA																						
conditio	7	5	PR1	2.0 V	0.7 V	2.0 V	2.0 V									2.0 V	0.7 V	2.0 V	2.0 V					-18 mA					1 5 1	33						0.4 V	3/	4.5 <	GND	
rminal c	5	4	CLK1	GND	GND	2/	2/									GND	GND	2/	2/				-18 mA							GND						4.5 V	0.4 V	0.4 V	4.5 V	
Te	4	ю	17 1	0.7 V	-	-	2.0 V									0.7 V	-	-	2.0 V			-18 mA							A E VI	0.4 V						4.5 V				
	ę	5	۲	0.7 V	-	-	2.0 V									0.7 V	-	-	2.0 V		-18 mA								111	4.5 V						4.5 V				
	2	-	CLR1	0.7 V	2.0 V	-	-									0.7 V	2.0 V	=	-	-18 mA				F		T			10	<u>م</u> 4.5 ۷					$\vdash$	GND	-	3/	0.4 V	
	Cases <u>1</u> / 2, X	Cases E, F	Test no.	-	2	e	4	5	9	7	8	6	10	11	12	13		15	16		18	19	20	21	22	23	24	25		28	29	30	31	32	33			+		38 tvne 09.
	MIL-STD-	883 method		3006	-	-	=	-	-	-	-	3007	-	=	-	=	-	=	-			I	1	1	1			1	0000	8 =	-	-	-	=						See footnotes at end of type 09.
	W	Symbol		V <sub>он</sub>								OL								2									_	2			IL4					╉	117	otnotes a
		Subgroup		-	Tc = 25°C															>													<u> </u>		. <u> </u>	_				See foc

# TABLE III. Group A inspection for device type 09.

		Unit		μA	=	=	-	-	-	-	-		-	=	-	-			=	=	-	mA	-	=	-	-	-																	Γ		
		its	Max	20	-	=	=	100	-	-	=	40	-	=	200	-		. 0	80	400	400	-100	-			8.0	8.0		See 7/	-			-		-	=	-	=	=	=			-	-	-	
		Limits	Min																			-15	-		-																1					
		Measured terminal		11	<u>к</u> 1	К 2	J2	J2	К 2	17 1	J1	CLK1		CLK2	CLK2	PR2	PR1	CLK1	CLR	CLR2	CLR1	۵ <sup>1</sup>	Q1	Q2	02	Vcc	V <sub>cc</sub>		AII	outputs		-	-			-	-	=	-	-			-	-	-	
	20	16	V <sub>cc</sub>	5.5 V	-	-	-	=	-	-	-		-	-	-	-				=	-	-	-			-	-		4.5 V	-					-	-	-	=	=	=			-	-	-	
	19	15	CLR2			GND	=	=	-				4 E V	GND	GND	4.5 V			2.7 V	5.5 V				4.5 V	GND	GND	5.5 V		A	-				= 0	۵ ۵	c =	-	=	=	=			-	-	в	4-
	18	14	J2			GND	2.7 V	6.5 V	GND				4 E V	-	-	-	_			4.5 V		-	ł			H			A	-					-	-	-	=	=	=	-		-	-	в	
or open	17	13	K 2			2.7 V 0		GND 5					4 E V 4	+		-		T	+	4.5 V 4	-						_		A	-		<u>ہ</u> =	-		-	-	-	-	=	=				-	-	
0.7 V, o	15	12	CLK2					ڻ -	2				+	╈	<u>ر</u>	9				GND 4						Ģ	Ģ		-		4	< ₪	1	œ =			В		В	В		_	_ ⊲	. 8		
Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open).						0 4.5 V			- -				_	-	D 5.5 V		_			_				0	>	V GND	_		-			< ₪	A		-	A		4			A.	< □			-	. 4
n ≥ 2.0 V, Iow	14	1	PR2			GND	4.5 V	4.5	BNI				. 2 0	GNI	GND	5.2			4.5	4.5 V				GND	4.5	5.5 V	GNI		В	A		-	-		-	-	-	-	=	В	ш·	< =	-	-	-	
oe high	13	10	02																					GND					т	=		-			-	т	Т			т			-	-	-	
nated may be high	12	ი	02 02																						GND				_	-		-	т		-	_		т	т	_			т	-	-	
signate	10	∞	GND	GND	-	=	=	-	-	-	-		-	=	-	-			-	-	-	-	-	-		-	-	intea.	GND	-		-	-		-	=	-	-	=	=			-	-	-	
not design	0	2	م'																			GND						F125°C and V <sub>IC</sub> tests are omitted.		-		-	т		-	_		т	т	_			т	-	-	
ns (pins	ω	9	g																				GND				1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	d Vic tests	H	-			_		-	т	т		_	т			_	1=	-	
onditior	7	ى ک	PR1	4.5 V	GND					GND	4.5 V	GND	2.1 V				5.5 V	GND	+.0 <		4.5 V	4.5 V	GND			5.5 V			В	A		-			=	-	-	-	=	в	а.	4 -	-	-	-	
minal c	2	4	CLK1	4.5 V	4.5 V					4.5 V	4.5 V	2.7 V	GIND				GND	2.5 V	GIAC		GND					GND	GND	cept I <sub>C</sub> =	B	в	4	< ₪	A	- ۵	-	A	В	A	в	в	A	4 د	₀∢	с <b>ш</b>	-	- ¥
Ter	4	ю	17 -	GND	2.7 V					5.5 V	-	4.5 V	-				4.5 V	4.5 V	+.0 <		4.5 V							oup 1, ex	A	-	- 0	<b>∩</b> =	-		-	=	-	-	=	=			-	-	-	
	e	2		2.7 V						GND		4.5 \	+		H	_	4.5 V	-	-		4.5 V					╞		for subar	A	-		-	-		=	=	=	=	=	=	= 1		-	-	в	
	0	<del>.</del>		GND 2						GND (		GND 4	+		╞	_	4.5 V 4	+	-		5.5 V 4	DNS	4.5 V			GND	5.5 V	d limits as	A	=		-	-	= C	0 ⊲	c =	-	=	=	=	= :		-	-	в	<b>4</b> =
	Cases <u>1</u> / 2, X	Cases E, F	o.	39 G		41	42	e.		45 G		47 G		2.0	1			1						61	22	63 G	14 5	same tests, terminal conditions, and limits as for subgroup 1, except $l_{\rm C}$ = . Same tests, terminal conditions, and limits as for subgroup 1, except $T_{\rm C}$ =	_	66	2	م م	0.	71	20	6.4	.2	76	2	8	6	Q 1	2	10	4	85 86
					4	4	4	4	4	4	4	4	1	r LO	5	Ω	u u	Ω L	2	20			9	9			9 22	ninal conc	9 1	9	9	9 9	2	~ ~			2	7	7	7	2	ω	100	8	8	88
	MIL-STD-	ol 883 method		3010	-	•	-	-	-	•	-		•	-	-	-			-	=	-	3011	•	-	•	3005	3006	tests, terr	3014			•	•		-	-	•	-	-	-		• •	•	-	•	
		p Symbol		ЧHI				IH2				H3			H4				ZHI	Ë	2	so				8		Same	Truth	C table	tests															
		Subgroup		٢	Tc = 25°C										_												c	νm	7 5/, 6/	$Tc = 25^{\circ}C$																

TABLE III. Group A inspection for device type 09.

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# MIL-M-38510/301F

		Unit																				MHz	-	-	=	su	-	=	-	-	-	-	-	-	-	-	=		-	=	=
		ts	Max	See 7/	-	-	-	-	-	-	=	-	-				-	-	=	=						20	-	-	-	32	-		-	24	-	-	-	35	8 =	-	-
		Limits	Min																			20	-	-	=	5	-	=		-			-	=	-	-	=	=	-	-	-
		Measured terminal	1	AI	outputs	-	-	=	-	=	-	=	-				-	=	-	=		6 G	۵1 1	ā 2	Q2	CLR1 to 01	PR1 to Q1	PR2 to Q2	CLR2 to G 2	CLR2 to Q2	PR2 to G 2	PR1 to 01	CLR1 to Q1	K1 to Q1-	CLK1 to 01	CLK2 to 02	CI K2 to Q2			CLK1 to 01	K1 to Q1
	20		V <sub>cc</sub>	4.5 V	-	-	-	-	-	-	=	-	-					-	=	-		5.0 V		-	-	ט -	- -	ч -	CL -	L C	= H	= =	LC	L L	с -	с -	⊑	5 C	5 -	с -	5 "
	19		CLR2 \	A 4	_		-	_		В	В	A						n <	r <	ς α		5		2.7 V	2.7 V			2.7 V	N	z	2.7 V					2.7 V	2.7 V	~ ~ ~	2.7 V		
										_	_					+						_								_								_			+
open).	18		J2	A	=	-	-	=	-	=	-	=	-	6	۰ <b>מ</b>	4 =	-		= ۵	-	_			0 2.7 V	2.7 V			_	/ 2.7 V		GND C					0 2.7 V	27V	+	2.7 V	<u> </u>	$\left  \right $
7 V, or	17	13	К 2 Х	В	-	-	-	-	-	-	-	-	-	< -			-		-	=				GND	GND			GND	2.7 V	2.7 V	GND					GND	GNL		GND		$\square$
ow ≤0.	15	12	CLK2	A	В	-	-	A	В	в	A	A	В	- a	₹ :		-		= ۵	=				Z	Z			Z	Z	Z	Z					Z	Z	2	Z		
2.0 V, Iow ≤ 0.7 V, or open).	14	11	PR2	A	-	В	A	-	-	-	-	-	-		(	<b>л</b> <	¥ <	∢ ۵	> ۵	< ⊲	<			2.7 V	2.7 V			Z	2.7 V	2.7 V	Z					2.7 V	771	27.1	2.7 V		
Terminal conditions (pins not designated may be high $\ge 2.0$ V, low	13	10	02	_	-	т	т	_	-	-	=	-	-		-	I :	Е-		= =	=	,				OUT			OUT		OUT							DUT	E D	200		
may be	12	თ	02	т	=	_	_	т	-	=	-	=	-					E _	J -	чт	-			OUT					OUT		OUT					OUT	T		OUT		Π
gnated	10	ω	GND	GND	=	-	-	=	-	=	-	=	-				-	=	=	=		GND	-	-	-	-	=		-	-			-	=	-	-	=	=	-	-	-
not desi	6	7	۰å	т		_	-	т	-	=	-	=	-					E _	J _	т	-		OUT			OUT						OUT			OUT	T				OUT	T
ns (pins no	8	9	a 1	_		т	т	_	-	=	=	=	-			I :	<b>E</b> -		= ]	=	1	OUT					OUT						OUT	OUT							OUT
nditions	7	ъ	PR1	A	-	в	A	-	-	-	=	-	-			я <	A <	< 0	<u> </u>	< ⊲	<	2.7 V	2.7 V			2.7 V	Z					z	7 \		2.7 V	t	1			2.7 V	2.7 V
ninal co	5	4	CLK1	A	В	-	-	A	в	В	A	A	в	а <	4 :				= ۵	=		z				z	Z					z	z			┢				z	z
Tern	4	e	к1 1	В	-	-		-	-	-	=	-	-	4 -					<u>-</u>	=		DNS	GND			2.7 V	GND					GND	2.7 V	SND	SND		T			GND	GND
	3	2	11	A	-	-		=	-	-	=	=	-	<u>а</u>	<b>р</b> -	¥ =			<u> </u>	=	55°C					2.7 V 2	GND (					GND (	2.7 V 2			+	+			2.7 V 0	2.7 V 0
	2	-	CLR1	A	=	-		=	-	В	В	A	-					n <	τ <	c a	and To = -	7 V 2	2.7 V 2			IN 2	2.7 V G					2.7 V G	IN 2			┢	+			2.7 V 2	2.7 V 2
					8	6	0	-					e S	~	0	5					-125°C :	5 2.		71			-		2	e S	4		1			6	ç	5 2	22		$\square$
	0		Test no.		8	ő	ര്	Ó	.6	б	ð	ல்	6	60	מֿ מ	5					0.7 at T <sub>c</sub> =	5 10	106	107		109			112	113	114	115			6 118	119	12		122	123	124
	MIL-STD-	ol 883 method		3014	-	-	•	-	-	-	-	-	-					-	-	=	subarour	Fig. 16	-	-	-	3003	Fig. 17	-	-	-	•	•	-		Fig. 16	-	-	-	-	-	-
		Symbol		Truth		tests															Reneat	fMAX	8			PLH1				PHL1				PLH2					2 HLZ		
		Subgroup		7 <u>5</u> /, <u>6</u> /	Tc = 25°(																œ	6	Tc = 25°C			t				t				t				+			

TABLE III. Group A inspection for device type 09.

See footnotes at end of device type 09.

# MIL-M-38510/301F

		Unit		MHz	su	-	-	-	
		ş	Мах		39	59	39	59	
		Limits	Min	20	5	=	=	-	
		Measured terminal	1						
	20	16	V <sub>cc</sub>						
	19	15	CLR2						
.(ne	18	14	J2						
/, or ope	17	13	K 2						
TABLE III. Group A inspection for device type 09. Terminal conditions (pins not designated may be high $\ge 2.0$ V, low $\le 0.7$ V, or open).	15	12	CLK2						
ce type ( 2.0 V, lo	14	1	PR2						
TABLE III. Group A inspection for device type 09. ons (pins not designated may be high $\ge 2.0$ V, low $\le$	13	10	02						
<u>pection</u> may be	12	6	02						
up A ins ignated	10	ω	GND		5°C.				ed.
III. Grou not des	6	7	°1 0		$t T_c = +12$				are omitte
TABLE I ns (pins	8	9	Q1		subgroup 9, except $T_{C} = +125^{\circ}C$ .				id V <sub>IC</sub> tests
conditio	2	പ	PR1		or subgrou				= -55°C ar
erminal	5	4	CLK1		Same tests and terminal conditions as for				except T <sub>c</sub>
Ĕ	4	ю	×۱ ۲		minal cond				bgroup 1,
	ε	5	۲		ts and terr				s as for su
	2	-	CLR1		Same tes				, and limits
	Cases <u>1</u> / 2, X	Cases E, F	Test no.	125-128	129-132	133-136	137-140	141-144	conditions
	MIL-STD-	883 method		Fig. 16	3003 Fig. 17	3003 Fig. 17	3003 Fig. 16	3003 Fig. 16	Same tests, terminal conditions, and limits as for subgroup 1, except $T_c = -55^{\circ}C$ and $V_c$ tests are omitted
		Symbol		f <sub>MAX</sub>	PLH1	PHL1	PLH2	PHL2	Same tes
		Subgroup Symbol 883 method		10					11
	-	~/		œ	4	t,	t	t	

 $\underline{1}'$  Case X and 2 pins not referenced are NC.  $\underline{2}'$ 

- - - 2.5 V minumum/5.5 V maximum > 0 -

 $\overline{3}$ / I<sub>IL</sub> limits in mA are as follows:

			Min/Max lir	Min/Max limits for CKT		
	A	В	С	D	Е	F
	075/250	030/300	095/210	160/400	135/370	160/400
			Min/Max lir	Min/Max limits for CKT		
IL4	A	В	С	D	Ш	Ъ
	150/500	060/700	160/400	320/800	120/360	320/800
	for tests 31,		for tests 31,		for tests 31,	
	32, 35, 36		32, 35, 36		32, 35, 36	
	200/800		350/760		350/760	
	for tests 33, 34		for tests 33, 34		for tests 33, 34	
			Min/Max lir	Min/Max limits for CKT		
IL7	A	В	C	D	ш	Ч
	200/800	060/700	350/760	560/-1.600	280/760	560/-1.600

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	IIL7	A	В	C	D	Ш	
		200/800	060/700	350/760	560/-1.600	280/760	56(
4							



 $\overline{5}/$  Input voltages shown are A = 2.0 volts minimum and B = 0.7 volts maximum.

6/ Tests shall be performed in sequence, attributes data only.

 $\overline{Z}/$  Output voltages shall be H  $\geq$  1.5 V and L < 1.5 V.

8/ f<sub>MAX</sub> minimum limit specified is the frequency of the input pulse. The output frequency shall be one-half of the input frequency.

### 6. NOTES

6.1 <u>Intended use.</u> Microcircuits conforming to this specification are intended for original equipment design applications and logistic support of existing equipment.

- 6.2 <u>Acquisition requirements.</u> Acquisition documents should specify the following:
  - a. Title, number, and date of the specification.
  - b. PIN and compliance identifier, if applicable (see 1.2).
  - c. Requirements for delivery of one copy of the conformance inspection data pertinent to the device inspection lot to be supplied with each shipment by the device manufacturer, if applicable.
  - d. Requirements for certificate of compliance, if applicable.
  - e. Requirements for notification of change of product or process to contracting activity in addition to notification to the qualifying activity, if applicable.
  - f. Requirements for failure analysis (including required test condition of method 5003 of MIL-STD-883), corrective action, and reporting of results, if applicable.
  - g. Requirements for product assurance options.
  - h. Requirements for special carriers, lead lengths, or lead forming, if applicable. These requirements should not affect the part number. Unless otherwise specified, these requirements will not apply to direct purchase by or direct shipment to the Government.
  - i. Requirements for "JAN" marking.
  - j. Packaging requirements (see 5.1).

6.3 <u>Superseding information</u>. The requirements of MIL-M-38510 have been superseded to take advantage of the available Qualified Manufacturer Listing (QML) system provided by MIL-PRF-38535. Previous references to MIL-M-38510 in this document have been replaced by appropriate references to MIL-PRF-38535. All technical requirements now consist of this specification and MIL-PRF-38535. The MIL-M-38510 specification sheet number and PIN have been retained to avoid adversely impacting existing government logistics systems and contractor's parts lists.

6.4 <u>Qualification</u>. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Manufacturers List QML-38535 whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or purchase orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from DSCC-VQ, 3990 E. Broad Street, Columbus, Ohio 43123-1199.

6.5 <u>Abbreviations, symbols, and definitions.</u> The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535, MIL-HDBK-1331, and as follows:

GND	Ground zero voltage potential
I <sub>IN</sub>	Current flowing into an input terminal
V <sub>IC</sub>	Input clamp voltage
V <sub>IN</sub>	Voltage level at an input terminal

6.6 <u>Logistic support</u>. Lead materials and finishes (see 3.4) are interchangeable. Unless otherwise specified, microcircuits acquired for Government logistic support will be acquired to device class B (see 1.2.2), lead material and finish A (see 3.4). Longer length leads and lead forming shall not affect the part number.

6.7 <u>Substitutability.</u> The cross-reference information below is presented for the convenience of users. Microcircuits covered by this specification will functionally replace the listed generic-industry type. Generic-industry microcircuit types may not have equivalent operational performance characteristics across military temperature ranges or reliability factors equivalent to MIL-M-38510 device types and may have slight physical variations in relation to case size. The presence of this information shall not be deemed as permitting substitution of generic-industry types for MIL-M-38510 types or as a waiver of any of the provisions of MIL-PRF-38535.

Military device	Generic-industry
type	type
01	54LS73
02	54LS74A
03	54LS112
04	54LS113
05	54LS114
06	54LS174
07	54LS175
08	54LS107
09	54LS109
10	54LS76A

6.8 <u>Manufacturers' designation</u>. Manufacturers' circuits, which form a part of this specification, are designated as shown in table IV herein.

			Mar	ufacturers			
Device	Texas Instru-	Signetics	National	Raytheon	Motorola	Fairchild	Advanced
type	ments Inc.	Corporation	Semiconductor Corp	Company	Inc	Semiconductor	Micro Devices
01	А	В	С	D	E		
02	А	В	С	D	E	F	
03	А	В	С	С	D	E	
04	А	В	С	С	F	Е	D
05	А		С	С	D	E	
06	А	В	С	E	F	G	D
07	А	В	С	E	F	G	D
08	А	В	С	D	Е		
09	А	В	С		Ш	F	
10	А	В	С	С	D	E	

TABLE IV. Manufacturers' designation.

6.9 <u>Changes from previous issue</u>. The margins of this specification are marked with vertical lines to indicate where changes from the previous issue were made. This was done as a convenience only and the Government assumes no libility whatsoever for any inaccuracies in these notations. Bidders and contractors are cautioned to evaluate the requirements of this document based on the entire content irrespective of the marginal notations and relationship to the last previous issue.

Custodians: Army - CR Navy - EC Air Force - 11 DLA - CC Preparing activity: DLA - CC

(Project 5962-2038)

Review activities: Army - MI, SM Navy - AS, CG, MC, SH, TD Air Force - 03, 19, 99

NOTE: The activities listed above were interested in this document as of the date of this document. Since organizations and responsibilities can change, you should verify the currency of the information above using the ASSIST Online database at www.dodssp.daps.mil.